

AIROC™ Bluetooth® LE module

General description

The Infineon AIROC™ CYBLE-022001-00 is a fully certified and qualified module supporting Bluetooth® Low Energy wireless communication. The CYBLE-022001-00 is a turnkey solution and includes on-board crystal oscillators, chip antenna, passive components, and Infineon PSoC™ 4 Bluetooth® LE. Refer to the PSoC™ 4 Bluetooth® LE [datasheet](#) for additional details on the capabilities of the PSoC™ 4 Bluetooth® LE device used on this module.

The CYBLE-022001-00 supports a number of peripheral functions (ADC, timers, counters, PWM) and serial communication protocols (I²C, UART, SPI) through its programmable architecture. The CYBLE-022001-00 includes a royalty-free Bluetooth® LE stack compatible with Bluetooth® 5.1 and provides up to 16 GPIOs in a small 10 × 10 × 1.80 mm package.

The CYBLE-022001-00 is a complete solution and an ideal fit for applications requiring Bluetooth® LE wireless connectivity.

Module description

- Module size: 10.0 mm × 10.0 mm × 1.80 mm (with shield)
- Bluetooth® 5.1 single-mode module
- Industrial temperature range: -40°C to +85°C
- 32-bit processor (0.9 DMIPS/MHz) with single-cycle 32-bit multiply, operating at up to 48 MHz
- 128-KB flash memory, 16-KB SRAM memory
- Watchdog timer with dedicated internal low-speed oscillator (ILO)
- Two-pin SWD for programming
- Up to 16 GPIOs configurable as open drain high/low, pull-up/pull-down, HI-Z analog, HI-Z digital, or strong output
- Certified to FCC, ISED, MIC, KC, and, CE regulations
 - FCC ID: WAP2001
 - IC ID: 7922A-2001
 - MIC ID: 005-101007
 - KC ID: MSIP-CRM-Cyp-2001
- Bluetooth® SIG 5.1 qualified
 - QDID: **141250**
 - Declaration ID: **U048555**

Power consumption

- TX output power: -18 dbm to +3 dbm
- Received signal strength indicator (RSSI) with 1-dB resolution
- TX current consumption of 15.6 mA (radio only, 0 dbm)
- RX current consumption of 16.4 mA (radio only)
- Low power mode support
 - Deep Sleep: 1.3 µA with watch crystal oscillator (WCO) on
 - Hibernate: 150 nA with SRAM retention
 - Stop: 60 nA with XRES wakeup

Functional capabilities

- Up to 15 capacitive sensors for buttons or sliders with best-in-class signal-to-noise ratio (SNR) and liquid tolerance
- 12-bit, 1-Msps SAR ADC with internal reference, sample-and-hold (S/H), and channel sequencer
- Two Serial Communication Blocks (SCBs) supporting I²C (master/slave), SPI (master/slave), or UART
- Four dedicated 16-bit timer, counter, or PWM blocks (TCPWMs)
- Programmable low voltage detect (LVD) from 1.8 V to 4.5 V
- I²S master interface
- Bluetooth® Low Energy protocol stack supporting generic access profile (GAP) Central, Peripheral, Observer, or Broadcaster roles
- Switches between Central and Peripheral roles on-the-go
- Standard Bluetooth® Low Energy profiles and services for interoperability
- Custom profile and service for specific use cases

Benefits

The CYBLE-022001-00 module is provided as a turnkey solution, including all necessary hardware required to use Bluetooth® LE communication standards.

- Proven, qualified, and certified hardware design ready to use
- Small footprint (10 × 10 mm × 1.80 mm), perfect for space constrained applications
- Reprogrammable architecture
- Fully certified module eliminates the time needed for design, development and certification processes
- Bluetooth® SIG qualified with QDID and Declaration ID
- Flexible communication protocol support
- PSoC™ Creator provides an easy-to-use integrated design environment (IDE) to configure, develop, program, and test a Bluetooth® LE application

More information

Infineon provides a wealth of data at www.infineon.com to help you to select the right module for your design, and to help you to quickly and effectively integrate the module into your design.

- Overview: [AIROC™ Bluetooth® & Multiprotocol](#)
- PSoC™ 4 BLE silicon datasheet
- Application notes: Infineon offers a number of BLE application notes covering a broad range of topics, from basic to advanced level. Recommended application notes for getting started with AIROC™ Bluetooth® LE modules are:
 - [AN96841](#) - Getting Started with EZ-BLE Module
 - [AN91267](#) - Getting started with PSoC™ 4 CY8C4xxx-BL MCU with AIROC™ Bluetooth® LE
 - [AN97060](#) - PSoC™ 4 BLE and PSoC™ 6 BLE - Over-The-Air (OTA) Device Firmware Upgrade (DFU) guide
 - [AN91162](#) - Creating a BLE Custom Profile
 - [AN91184](#) - PSoC™ 4 BLE - Designing BLE Applications
 - [AN92584](#) - Designing for Low Power and Estimating Battery Life for BLE Applications
 - [AN85951](#) - PSoC™ 4 and PSoC™ 6 MCU CAPSENSE™ design guide
 - [AN95089](#) - PSoC™ 4/PSoC™ 6 BLE Crystal Oscillator Selection and Tuning Techniques
 - [AN91445](#) - Antenna Design and RF Layout Guidelines

Two easy-to-use design environments to get you started quickly

- Technical reference manual (TRM):
 - PSoC™ BLE [Technical reference manual](#)
- Knowledge base articles
 - [KBA97279](#) - Pin Mapping Differences Between the EZ-BLE™ Creator Evaluation Board (CYBLE-022001-EVAL) and the BLE Pioneer Kit (CY8CKIT-042-BLE)
 - [KBA97094](#) - RF Regulatory Certifications for EZ-BLE™ Creator Module
 - [KBA97095](#) - EZ-BLE™ Module Placement
 - [KBA213976](#) - FAQ for BLE and Regulatory Certifications with EZ-BLE modules
 - [KBA210802](#) - Queries on BLE Qualification and Declaration Processes
 - [KBA218122](#) - 3D Model Files for EZ-BLE/EZ-BT Modules
- Development kits:
 - [CYBLE-022001-EVAL](#), CYBLE-022001-00 Evaluation Board
 - [CY8CKIT-042-BLE](#), Bluetooth® Low Energy Pioneer Kit
 - [CY8CKIT-002](#), PSoC™ MiniProg3 Program and Debug Kit
- Test and debug tools:
 - [CYSmart](#), AIROC™ Bluetooth® Connect App — Bluetooth® LE Test and Debug Tool
 - [CYSmart Mobile](#), AIROC™ Bluetooth® Connect App— Mobile App

Two easy-to-use design environments to get you started quickly

1. PSoC™ Creator Integrated Design Environment (IDE)

PSoC™ Creator is an Integrated Design Environment (IDE) that enables concurrent hardware and firmware editing, compiling and debugging of PSoC™ 3, PSoC™ 4, PSoC™ 5LP, PSoC™ 4 Bluetooth® LE, and AIROC™ Bluetooth® LE module systems with no code size limitations. PSoC™ peripherals are designed using schematic capture and simple graphical user interface (GUI) with over 120 pre-verified, production-ready PSoC™ Components.

PSoC™ Components are analog and digital “virtual chips,” represented by an icon that users can drag-and-drop into a design and configure to suit a broad array of application requirements.

2. PSoC™ Creator Component Datasheet - Bluetooth Low Energy (BLE)

The **PSoC™ Creator Component Datasheet - Bluetooth Low Energy (BLE)** provides a comprehensive GUI-based configuration window that lets you quickly design Bluetooth® LE applications. The Component incorporates a Bluetooth® Core Specification v5.1 compliant Bluetooth® LE protocol stack and provides API functions to enable user applications to interface with the underlying Bluetooth® Low Energy Sub-System (BLESS) hardware via the stack.

AIROC™ Bluetooth® & Bluetooth® LE module firmware platform

The **AIROC™ Bluetooth® & Bluetooth® LE module firmware platform** provides a simple way to access the most common hardware and communication features needed in Bluetooth® LE applications. AIROC™ Bluetooth® & Bluetooth® LE module firmware implements an intuitive API protocol over the UART interface and exposes various status and control signals through the module's GPIOs, making it easy to add Bluetooth® LE functionality quickly to existing designs.

Use a simple serial terminal and evaluation kit to begin development without requiring an IDE. Refer to the AIROC™ Bluetooth® & Bluetooth® LE module firmware webpage for User Manuals and instructions for getting started as well as detailed reference materials.

AIROC™ Bluetooth® LE modules are pre-flashed with the AIROC™ Bluetooth® & Bluetooth® LE module firmware platform. If you do not have AIROC™ Bluetooth® & Bluetooth® LE module firmware pre-loaded on your module, you can download each AIROC™ Bluetooth® LE module's firmware images on the [AIROC™ Bluetooth® & Bluetooth® LE module firmware webpage](#).

Technical support

- **Frequently asked questions (FAQs)**: Learn more about our Bluetooth® LE ECO System.
- **Forum**: See if your question is already answered by fellow developers on the PSoC™ 4 Bluetooth® LE forum.
- Visit our **support** page and create a **technical support case** or contact a **local sales representatives**. If you are in the United States, you can talk to our technical support team by calling our toll-free number: +1-800-541-4736. Select option 2 at the prompt.

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1 Overview

1.1 Module description

The CYBLE-022001-00 module is a complete module designed to be soldered to the applications main board.

Module dimensions and drawing:

Infineon reserves the right to select components (including the appropriate Bluetooth® LE device) from various vendors to achieve the Bluetooth® LE module functionality. Such selections will still guarantee that all height restrictions of the component area are maintained. Designs should be held within the physical dimensions shown in the mechanical drawings in [Figure 1](#). All dimensions are in millimeters (mm).

Table 1 **Module design dimensions**

Dimension item		Specification
Module dimensions	Length (X)	10.00 ± 0.15 mm
	Width (Y)	10.00 ± 0.15 mm
Antenna location dimensions	Length (X)	7.00 ± 0.15 mm
	Width (Y)	5.00 ± 0.15 mm
PCB thickness	Height (H)	0.50 ± 0.10 mm
Shield height	Height (H)	1.10 ± 0.10 mm
Maximum component height	Height (H)	1.30-mm typical (chip antenna)
Total module thickness (bottom of module to highest component)	Height (H)	1.80-mm typical

See [Figure 1](#) for the mechanical reference drawing for CYBLE-022001-00.

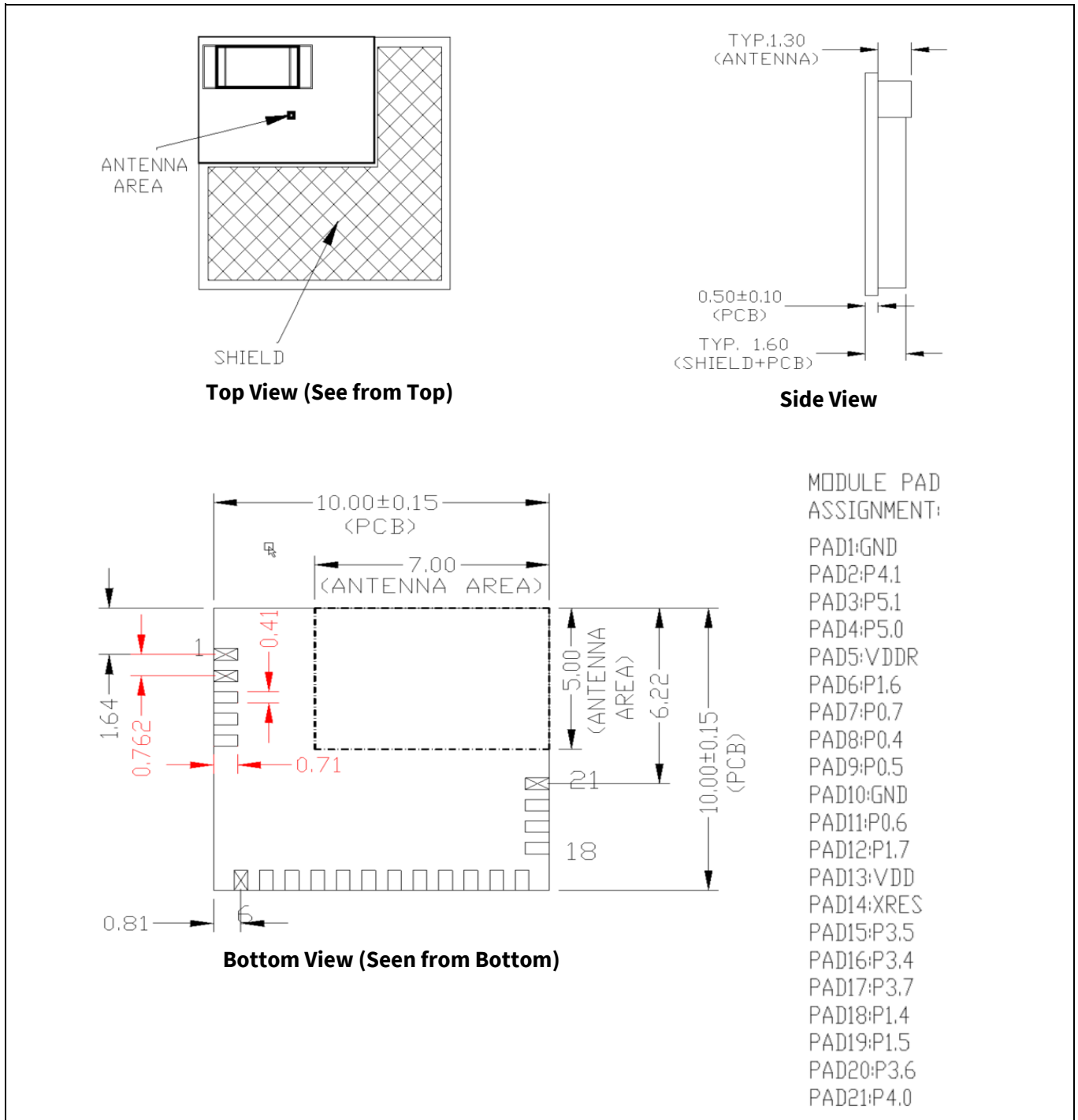


Figure 1 Module mechanical drawing

Note

1. No metal should be located beneath or above the antenna area. Only bare PCB material should be located beneath the antenna area. For more information on recommended host PCB layout, see [“Recommended host PCB layout”](#) on page 10.

2 Pad connection interface

As shown in the bottom view of [Figure 1](#), the CYBLE-022001-00 connects to the host board via solder pads on the back of the module. [Table 2](#) and [Figure 2](#) detail the solder pad length, width, and pitch dimensions of the CYBLE-022001-00 module.

Table 2 Solder pad connection description

Name	Connections	Connection type	Pad length dimension	Pad width dimension	Pad pitch
SP	21	Solder Pads	0.71 mm	0.41 mm	0.76 mm

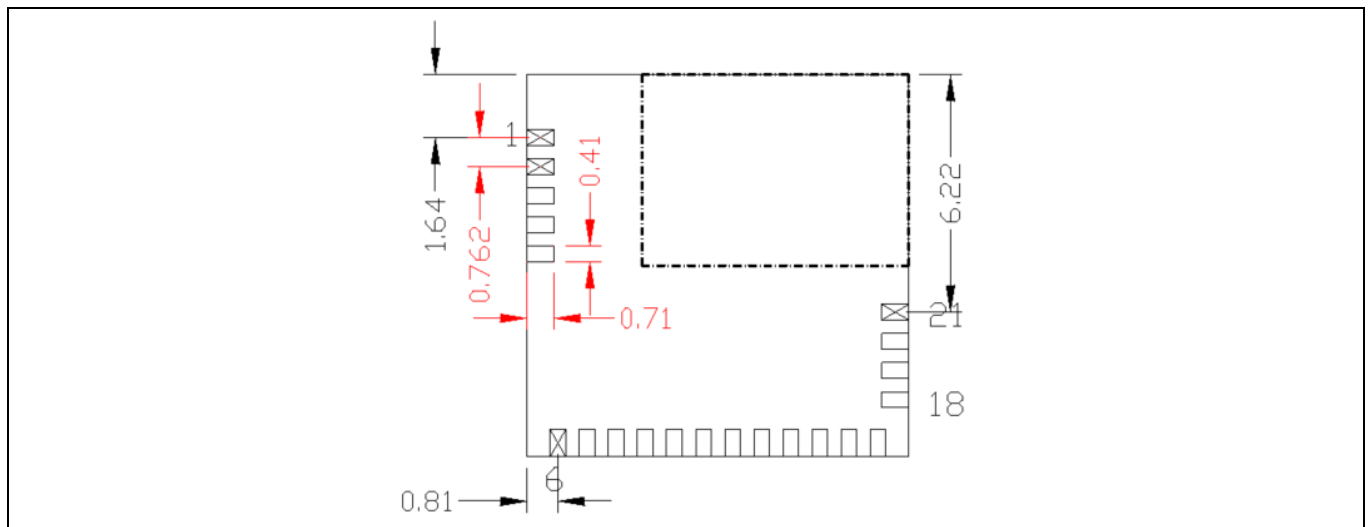


Figure 2 Solder pad dimensions (seen from bottom)

To maximize RF performance, the host layout should follow these recommendations:

3. The ideal placement of the Infineon Bluetooth® LE module is in a corner of the host board with the chip antenna located at the far corner. This placement minimizes the additional recommended keep out area stated in item 2. Refer to [AN96841](#) for module placement best practices.
4. To maximize RF performance, the area immediately around the Infineon Bluetooth® LE module chip antenna should contain an additional keep out area, where no grounding or signal traces are contained. The keep out area applies to all layers of the host board. The recommended dimensions of the host PCB keep out area are shown in [Figure 4](#) (dimensions are in mm).

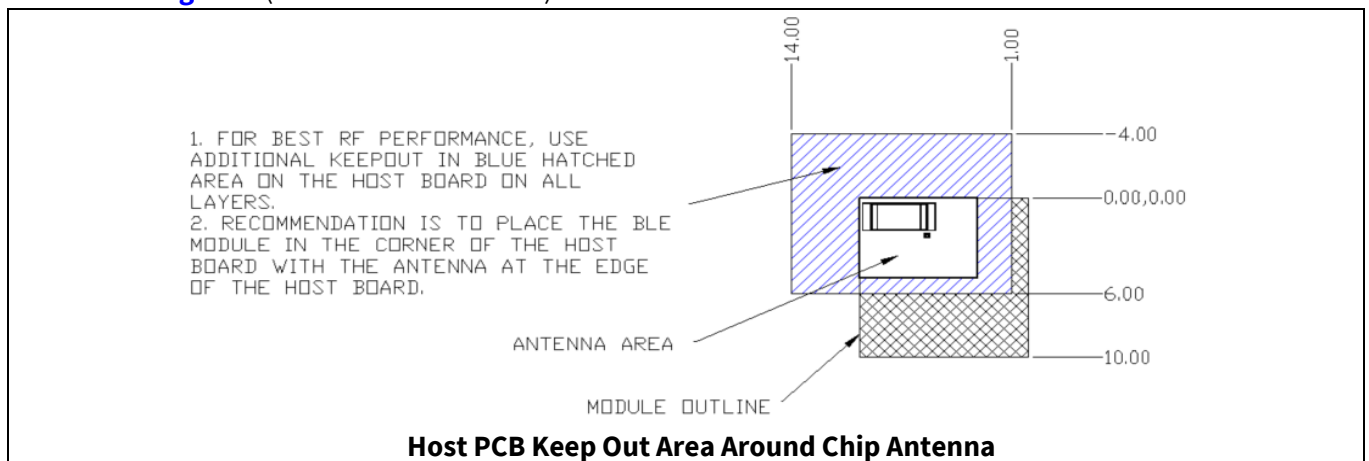


Figure 3 Recommended host PCB keep out area around the CYBLE-022001-00 chip antenna

3 Recommended host PCB layout

Figure 4, Figure 5, Figure 6, and Table 3 provide details that can be used for the recommended host PCB layout pattern for the CYBLE-022001-00. Dimensions are in millimeters unless otherwise noted. Pad length of 0.91 mm (0.455 mm from center of the pad on either side) shown in Figure 6 is the minimum recommended host pad length. The host PCB layout pattern can be completed using either Figure 4, Figure 5, or Figure 6. It is not necessary to use all figures to complete the host PCB layout pattern.

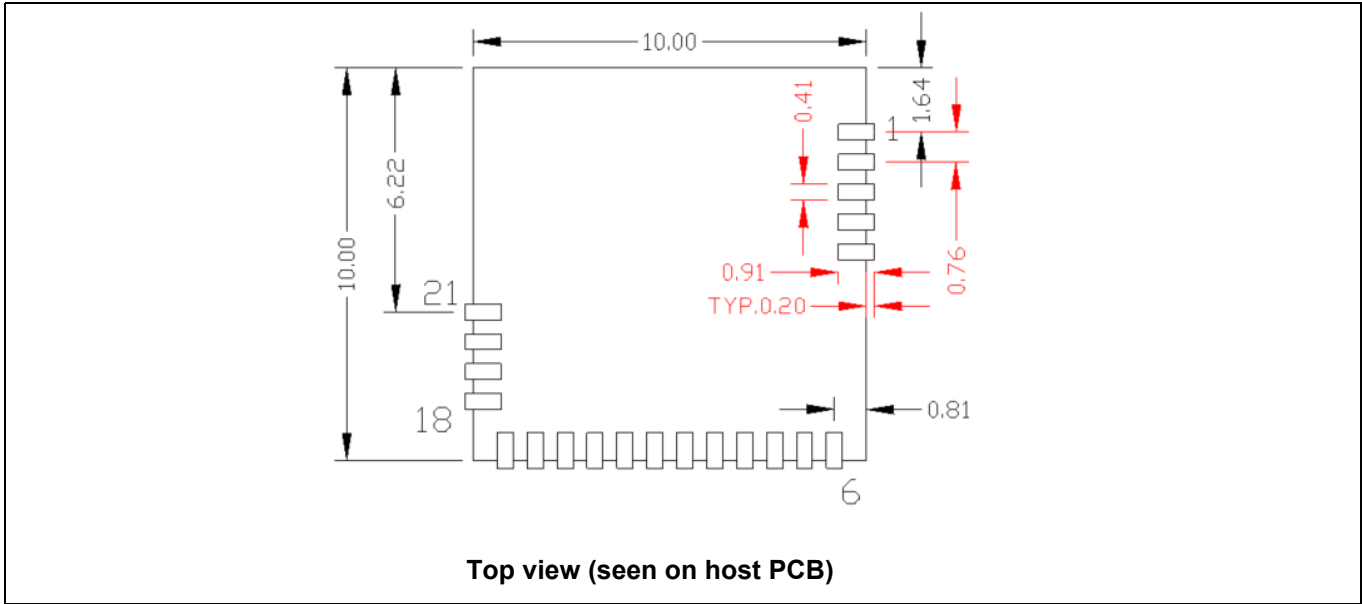


Figure 4 Host layout pattern for CYBLE-022001-00

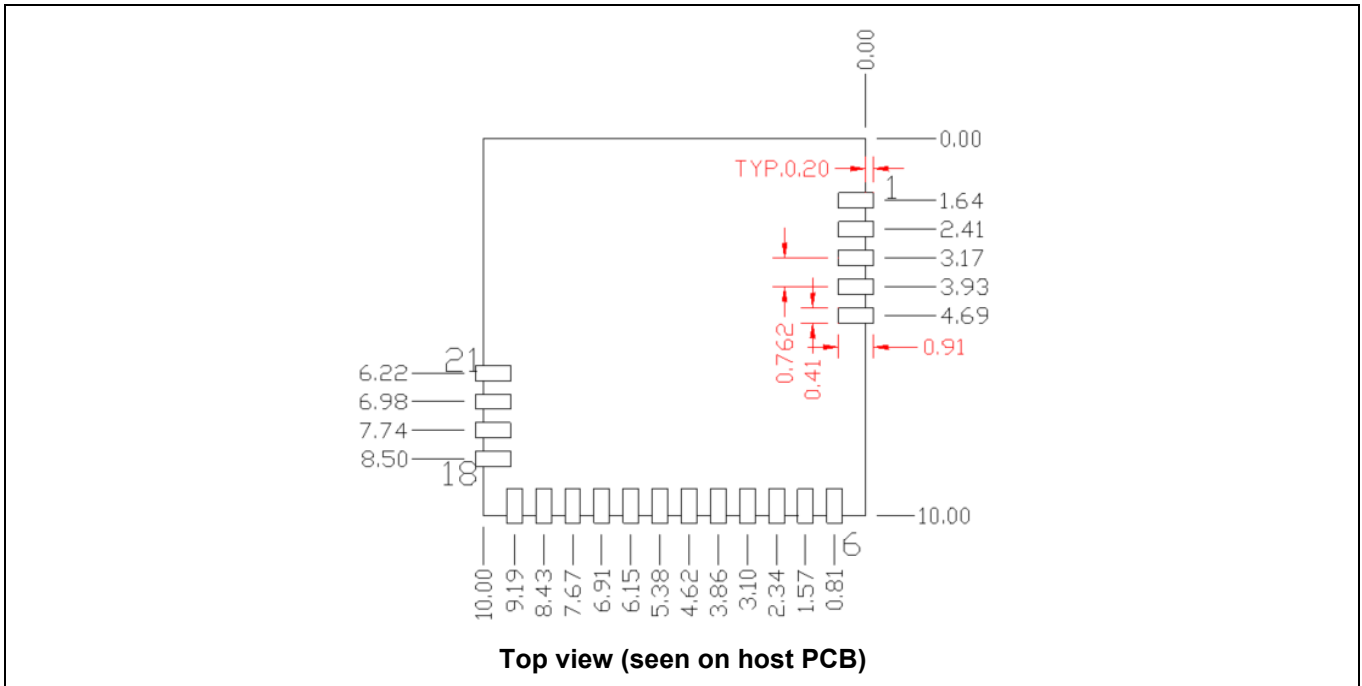


Figure 5 Module pad location from origin

Recommended host PCB layout

Table 3 provides the center location for each solder pad on the CYBLE-022001-00. All dimensions are referenced to the center of the solder pad. Refer to **Figure 6** for the location of each module solder pad.

Table 3 Module solder pad location

Solder pad (Center of pad)	Location (X,Y) from origin (mm)	Dimension from origin (mils)
1	(0.26, 1.64)	(10.24, 64.57)
2	(0.26, 2.41)	(10.24, 94.88)
3	(0.26, 3.17)	(10.24, 124.80)
4	(0.26, 3.93)	(10.24, 154.72)
5	(0.26, 4.69)	(10.24, 184.65)
6	(0.81, 9.74)	(31.89, 383.46)
7	(1.57, 9.74)	(61.81, 383.46)
8	(2.34, 9.74)	(92.13, 383.46)
9	(3.10, 9.74)	(122.05, 383.46)
10	(3.86, 9.74)	(151.97, 383.46)
11	(4.62, 9.74)	(181.89, 383.46)
12	(5.38, 9.74)	(211.81, 383.46)
13	(6.15, 9.74)	(242.13, 383.46)
14	(6.91, 9.74)	(272.05, 383.46)
15	(7.67, 9.74)	(301.97, 383.46)
16	(8.43, 9.74)	(331.89, 383.46)
17	(9.19, 9.74)	(361.81, 383.46)
18	(9.75, 8.50)	(383.86, 334.65)
19	(9.75, 7.74)	(383.86, 304.72)
20	(9.75, 6.98)	(383.86, 274.80)
21	(9.75, 6.22)	(383.86, 244.88)

Recommended host PCB layout

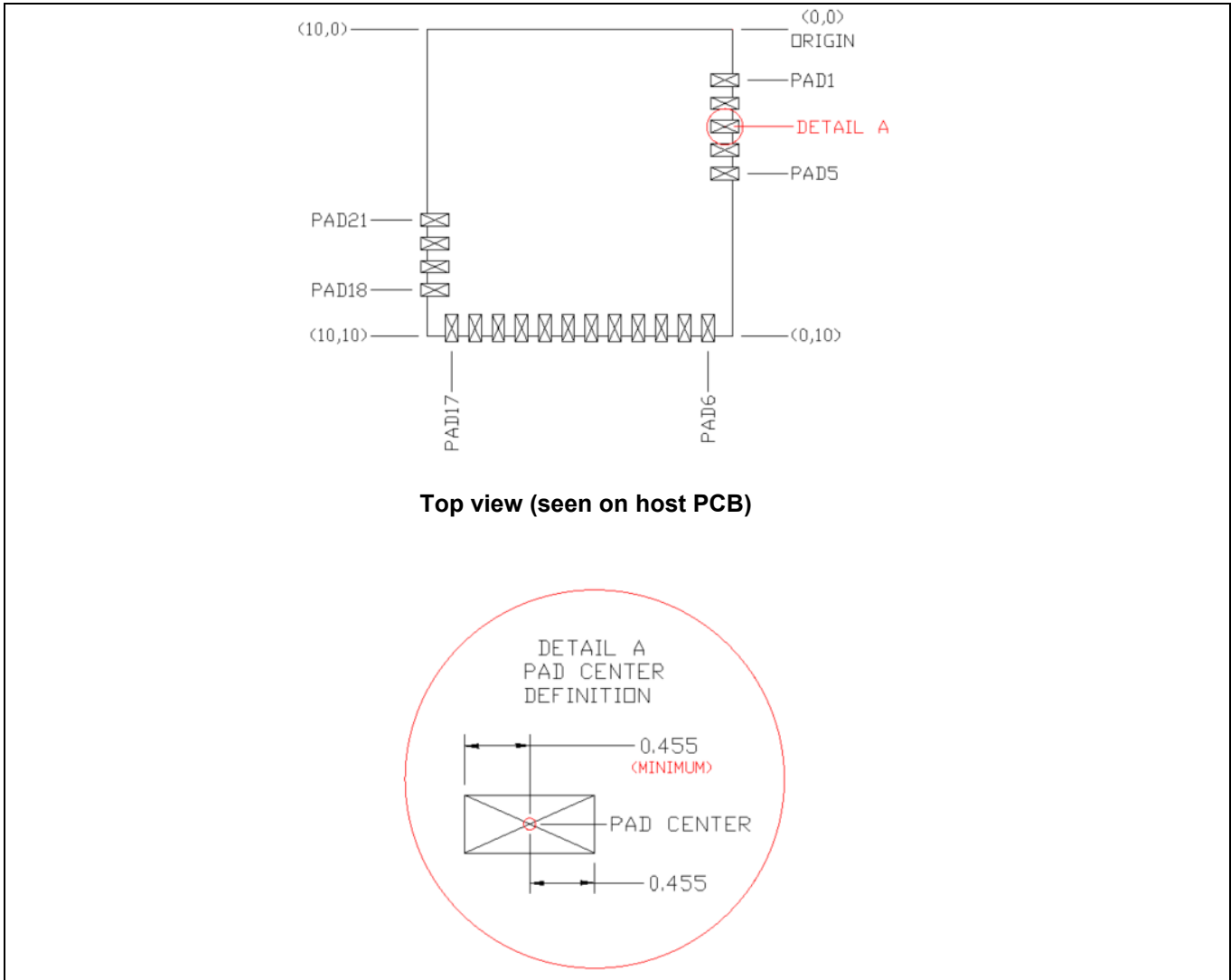


Figure 6 Solder pad reference location

Digital and analog capabilities and connections

4 Digital and analog capabilities and connections

Table 4 details the solder pad connection definitions and available functions for each connection pad. **Table 4** lists the solder pads on CYBLE-022001-00, the Bluetooth® LE device port-pin, and denotes whether the function shown is available for each solder pad. Each connection is configurable for a single option shown with a ✓.

Table 4 Solder pad connection definitions

Solder pad number	Device port pin	UART	SPI	I ² C	TCPWM ^[2,3]	CapSense	WCO Out	ECO Out	LCD	SWD	GPIO
1	GND ^[4]	Ground Connection									
2	P4.1 ^[5]	✓(SCB1_CTS)	✓(SCB1_MISO)		✓(TCPWM0_N)	✓(Sensor/ C _{TANK})			✓		✓
3	P5.1	✓(SCB1_TX)	✓(SCB1_SCLK)	✓(SCB1_SCL)	✓(TCPWM3_N)	✓(Sensor)		✓	✓		✓
4	P5.0	✓(SCB1_RX)	✓(SCB1_SS0)	✓(SCB1_SDA)	✓(TCPWM3_P)	✓(Sensor)			✓		✓
5	V _{DDR}	Radio Power Supply (1.9V to 5.5V)									
6	P1.6	✓(SCB0_RTS)	✓(SCB0_SS0)		✓(TCPWM)	✓(Sensor)			✓		✓
7	P0.7	✓(SCB0_CTS)	✓(SCB0_SCLK)		✓(TCPWM)	✓(Sensor)			✓	✓ (SWDCLK)	✓
8	P0.4	✓(SCB0_RX)	✓(SCB0_MOSI)	✓(SCB0_SDA)	✓(TCPWM)	✓(Sensor)		✓	✓		✓
9	P0.5	✓(SCB0_TX)	✓(SCB0_MISO)	✓(SCB0_SCL)	✓(TCPWM)	✓(Sensor)			✓		✓
10	GND	Ground Connection									
11	P0.6	✓(SCB0_RTS)	✓(SCB0_SS0)		✓(TCPWM)	✓(Sensor)			✓	✓ (SWDIO)	✓
12	P1.7	✓(SCB0_CTS)	✓(SCB0_SCLK)		✓(TCPWM)	✓(Sensor)			✓		✓
13	V _{DD}	Digital Power Supply Input (1.71 to 5.5V)									
14	XRES	External Reset Hardware Connection Input									
15	P3.5	✓(SCB1_TX)		✓(SCB1_SCL)	✓(TCPWM)	✓(Sensor)			✓		✓
16	P3.4	✓(SCB1_RX)		✓(SCB1_SDA)	✓(TCPWM)	✓(Sensor)			✓		✓
17	P3.7	✓(SCB1_CTS)			✓(TCPWM)	✓(Sensor)	✓		✓		✓
18	P1.4	✓(SCB0_RX)	✓(SCB0_MOSI)	✓(SCB0_SDA)	✓(TCPWM)	✓(Sensor)			✓		✓
19	P1.5	✓(SCB0_TX)	✓(SCB0_MISO)	✓(SCB0_SCL)	✓(TCPWM)	✓(Sensor)			✓		✓
20	P3.6	✓(SCB1_RTS)			✓(TCPWM)	✓(Sensor)			✓		✓
21	P4.0 ^[6]	✓(SCB1_RTS)	✓(SCB1_MOSI)		✓(TCPWM0_P)	✓(C _{MOD})			✓		✓

Notes

- TCPWM stands for timer, counter, and PWM. If supported, the pad can be configured to any of these peripheral functions.
- TCPWM connections on ports 0, 1, 2, and 3 can be routed through the Digital Signal Interconnect (DSI) to any of the TCPWM blocks and can be either positive or negative polarity. TCPWM connections on ports 4 and 5 are direct and can only be used with the specified TCPWM block and polarity specified above.
- The main board needs to connect both GND connections (Pad 1 and Pad 10) on the module to the common ground of the system.
- When using the capacitive sensing functionality, Pad 2 (P4.1) can be connected to a C_{TANK} capacitor (located off of Infineon Bluetooth® LE Module). C_{Tank} should be used if implementing a shield layer on the capacitive sensor. If used, this capacitor should be placed as close to the module as possible.
- When using the capacitive sensing functionality, Pad 21 (P4.0) must be connected to a C_{MOD} capacitor (located off of Infineon Bluetooth® LE Module). The value of this capacitor is 2.2 nF and should be placed as close to the module as possible.
- If the I²S feature is used in the design, the I²S pins shall be dynamically routed to the appropriate available GPIO by PSoC™ Creator

Power supply connections and recommended external components

5 Power supply connections and recommended external components

5.1 Power connections

The CYBLE-022001-00 contains two power supply connections, VDD and VDDR. The VDD connection supplies power for both digital and analog device operation. The VDDR connection supplies power for the device radio.

VDD accepts a supply range of 1.71 V to 5.5 V. VDDR accepts a supply range of 1.9 V to 5.5 V. These specifications can be found in [Table 9](#). The maximum power supply ripple for both power connections on the module is 100 mV, as shown in [Table 7](#).

The power supply ramp rate of VDD must be equal to or greater than that of VDDR.

5.2 Connection options

Two connection options are available for any application:

- Single supply: Connect VDD and VDDR to the same supply.
- Independent supply: Power VDD and VDDR separately.

5.3 External component recommendation

In either connection scenario, it is recommended to place an external ferrite bead between the supply and the module connection. The ferrite bead should be positioned as close as possible to the module pin connection.

[Figure](#) details the recommended host schematic options for a single supply scenario. The use of one or two ferrite beads will depend on the specific application and configuration of the CYBLE-022001-00.

[Figure 8](#) details the recommended host schematic for an independent supply scenario.

The recommended ferrite bead value is 330 Ω , 100 MHz (Murata BLM21PG331SN1D).

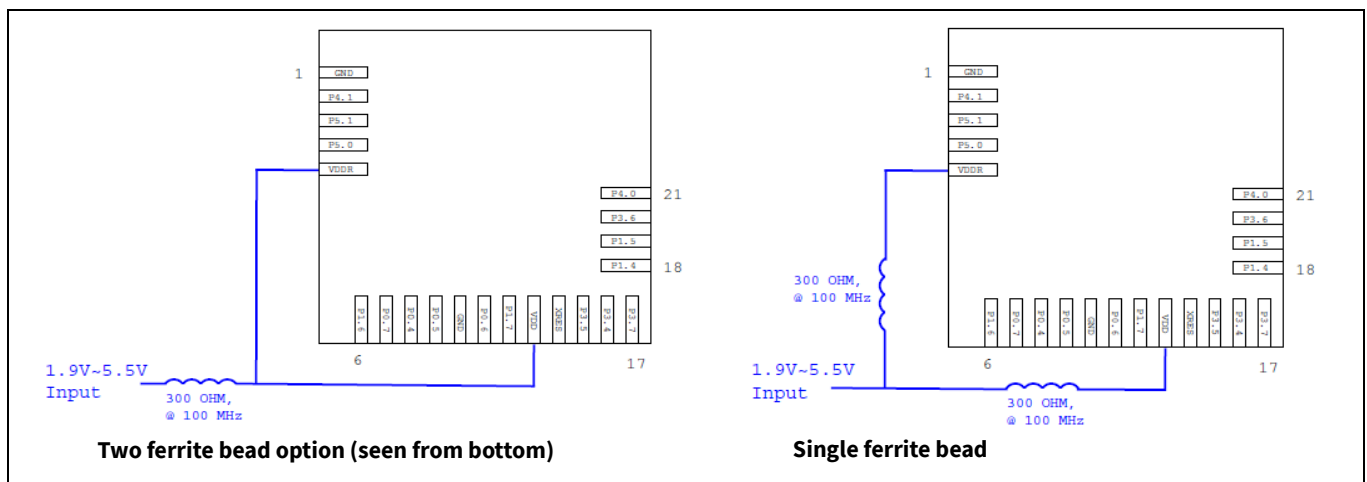


Figure 7 Recommended host schematic options for a Single Supply Option

Power supply connections and recommended external components

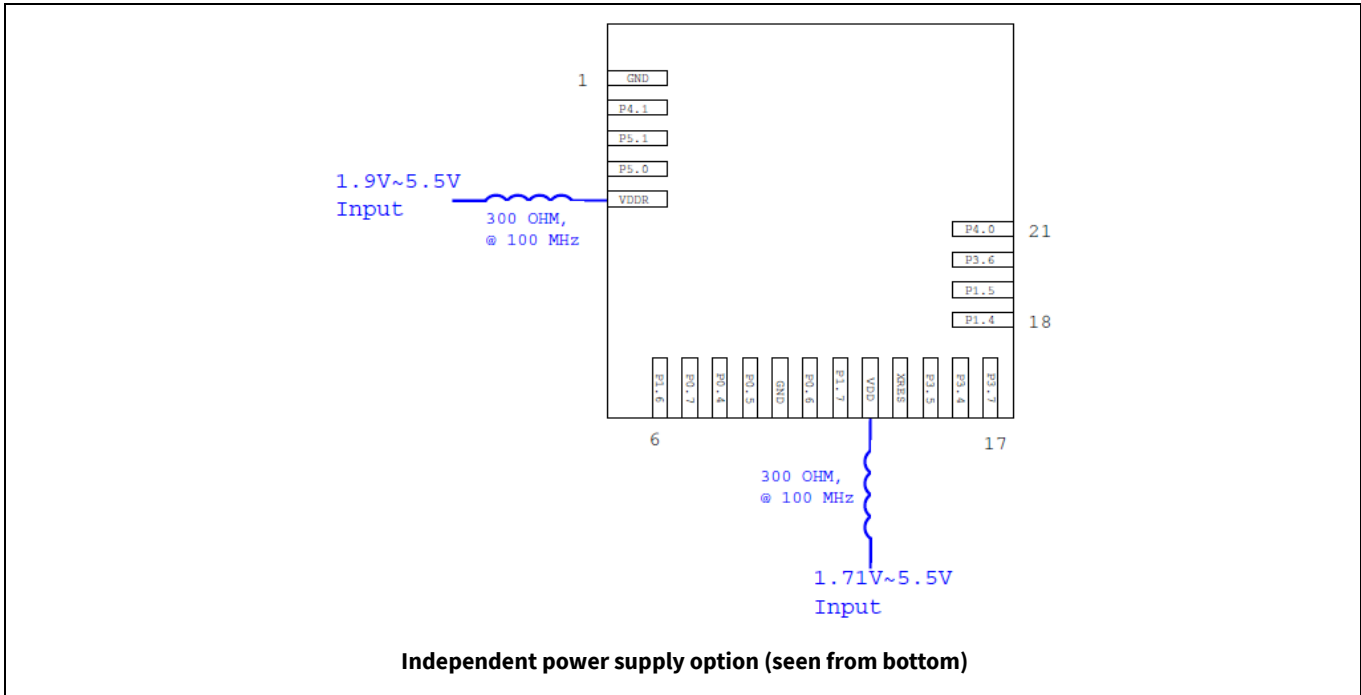


Figure 8 Recommended host schematic for an independent supply option

Power supply connections and recommended external components

The CYBLE-022001-00 schematic is shown in **Figure 9**.

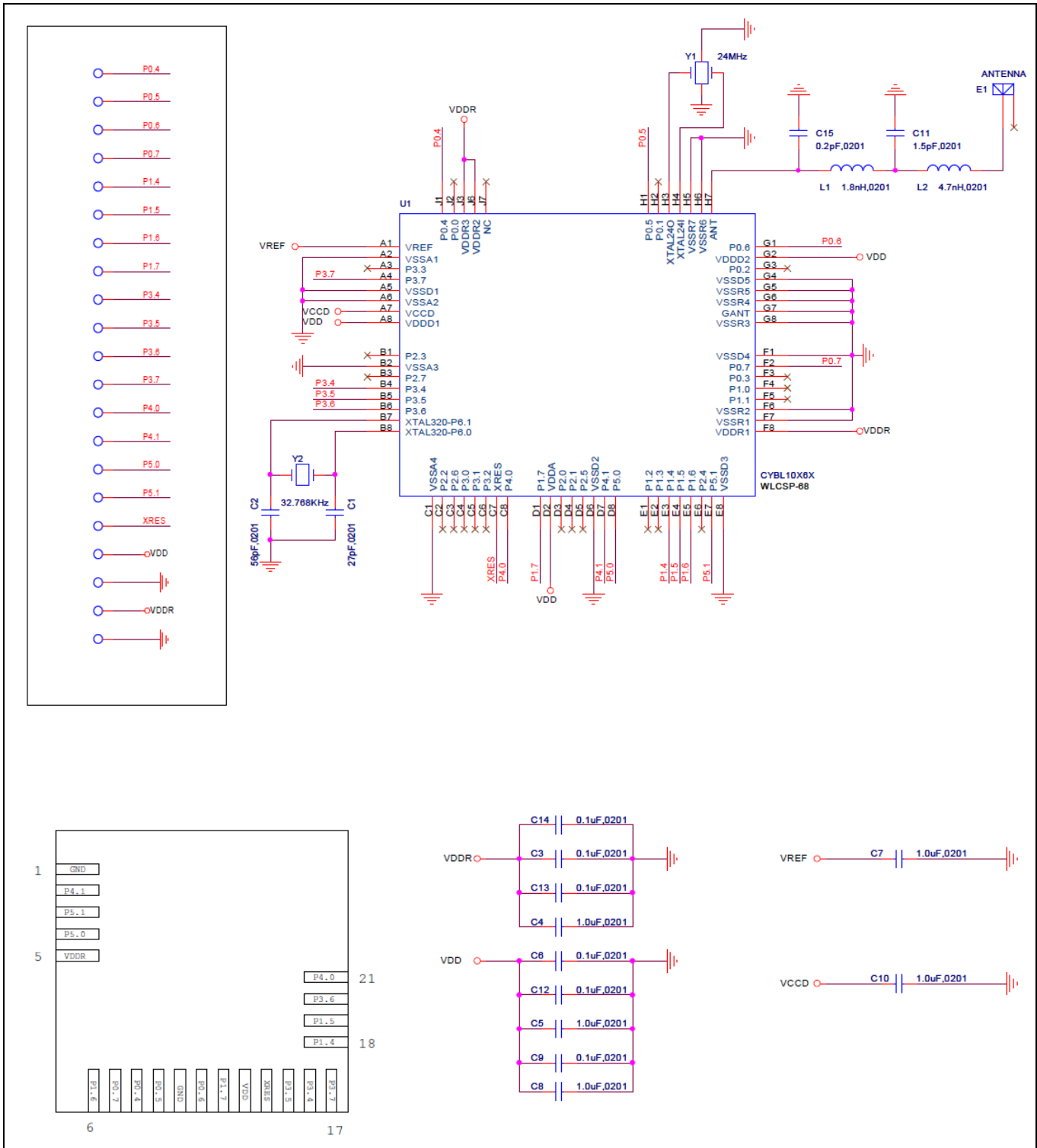


Figure 9 CYBLE-022001-00 schematic diagram

Power supply connections and recommended external components

5.4 Critical components list

Table 5 details the critical components used in the CYBLE-022001-00 module.

Table 5 Critical component list

Component	Reference designator	Description
Silicon	U1	68-pin WLCSP PSoC™ 4 Bluetooth® LE
Crystal	Y1	24.000 MHz, 10PF
Crystal	Y2	32.768 kHz, 12.5PF
Antenna	E1	2.4–2.5 GHz chip antenna

5.5 Antenna design

Table 6 details the chip antenna used in the CYBLE-022001-00 module. The specifications listed are according to the vendor's datasheet. The Infineon module performance improves many of these characteristics. For more information, see **Table 6**.

Table 6 Chip antenna specifications

Item	Description
Chip antenna manufacturer	Johanson Technology Inc.
Chip antenna part number	2450AT18B100
Frequency range	2400–2500 MHz
Peak gain	0.5-dBi typical
Average gain	–0.5-dBi typical
Return loss	9.5-dB minimum

6 Electrical specification

Table 7 details the absolute maximum electrical characteristics for the Infineon Bluetooth® LE module.

Table 7 CYBLE-022001-00 absolute maximum ratings

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
V_{DDD_ABS}	Analog, digital, or radio supply relative to V_{SS} ($V_{SSD} = V_{SSA}$)	-0.5	-	6	V	Absolute maximum
V_{CCD_ABS}	Direct digital core voltage input relative to V_{SSD}	-0.5	-	1.95		Absolute maximum
V_{DDD_RIPPLE}	Maximum power supply ripple for V_{DD} and V_{DDR} input voltage	-	-	100	mV	3.0-V supply Ripple frequency of 100 kHz to 750 kHz
V_{GPIO_ABS}	GPIO voltage	-0.5	-	$V_{DD} + 0.5$	V	Absolute maximum
I_{GPIO_ABS}	Maximum current per GPIO	-25	-	25	mA	Absolute maximum
$I_{GPIO_in-junction}$	GPIO injection current: Maximum for $V_{IH} > V_{DD}$ and minimum for $V_{IL} < V_{SS}$	-0.5	-	0.5		Absolute maximum current injected per pin
LU	Pin current for latch up	-200		200		-

Table 8 details the RF characteristics for the Infineon Bluetooth® LE module.

Table 8 CYBLE-022001-00 RF performance characteristics

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
RF_O	RF output power on ANT	-18	0	3	dBm	Configurable via register settings
RX_S	RF receive sensitivity on ANT	-	-87	-		Guaranteed by design simulation
F_R	Module frequency range	2400	-	2480	MHz	-
G_P	Peak gain	-	0.5	-	dBi	-
G_{Avg}	Average gain	-	-0.5	-		-
RL	Return loss	-	-10.5	-	dB	-

Electrical specification

Table 9 through **Table 46** list the module-level electrical characteristics for the CYBLE-022001-00. All specifications are valid for $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$ and $T_J \leq 100^{\circ}\text{C}$, except where noted. Specifications are valid for 1.71 V to 5.5 V, except where noted.

Table 9 CYBLE-022001-00 DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
V _{DD1}	Power supply input voltage	1.8	–	5.5	V	With regulator enabled
V _{DD2}	Power supply input voltage unregulated	1.71	1.8	1.89		Internally unregulated supply
V _{DDR1}	Radio supply voltage (radio on)	1.9	–	5.5		–
V _{DDR2}	Radio supply voltage (radio off)	1.71	–	5.5		–
Active Mode, V _{DD} = 1.71 V to 5.5 V						
I _{DD3}	Execute from flash; CPU at 3 MHz	–	1.7	–	mA	T = 25°C, V _{DD} = 3.3 V
I _{DD4}	Execute from flash; CPU at 3 MHz	–	–	–		T = –40°C to 85°C
I _{DD5}	Execute from flash; CPU at 6 MHz	–	2.5	–		T = 25°C, V _{DD} = 3.3 V
I _{DD6}	Execute from flash; CPU at 6 MHz	–	–	–		T = –40°C to 85°C
I _{DD7}	Execute from flash; CPU at 12 MHz	–	4	–	mA	T = 25°C, V _{DD} = 3.3 V
I _{DD8}	Execute from flash; CPU at 12 MHz	–	–	–		T = –40°C to 85°C
I _{DD9}	Execute from flash; CPU at 24 MHz	–	7.1	–		T = 25°C, V _{DD} = 3.3 V
I _{DD10}	Execute from flash; CPU at 24 MHz	–	–	–		T = –40°C to 85°C
I _{DD11}	Execute from flash; CPU at 48 MHz	–	13.4	–		T = 25°C, V _{DD} = 3.3 V
I _{DD12}	Execute from flash; CPU at 48 MHz	–	–	–		T = –40°C to 85°C
Sleep Mode, V _{DD} = 1.8 V to 5.5 V						
I _{DD13}	IMO on	–	–	–	mA	T = 25°C, V _{DD} = 3.3 V, SYSCLK = 3 MHz
Sleep Mode, V _{DD} and V _{DDR} = 1.9 V to 5.5 V						
I _{DD14}	ECO on	–	–	–	mA	T = 25°C, V _{DD} = 3.3 V, SYSCLK = 3 MHz
Deep-Sleep Mode, V _{DD} = 1.8 V to 3.6 V						
I _{DD15}	WDT with WCO on	–	1.5	–	μA	T = 25°C, V _{DD} = 3.3 V
I _{DD16}	WDT with WCO on	–	–	–		T = –40°C o 85°C
I _{DD17}	WDT with WCO on	–	–	–		T = 25°C, V _{DD} = 5 V
I _{DD18}	WDT with WCO on	–	–	–		T = –40°C to 85°C
Deep-Sleep Mode, V _{DD} = 1.71 V to 1.89 V (regulator bypassed)						
I _{DD19}	WDT with WCO on	–	–	–	μA	T = 25°C
I _{DD20}	WDT with WCO on	–	–	–		T = –40°C to 85°C
Hibernate Mode, V _{DD} = 1.8 V to 3.6 V						

Electrical specification

Table 9 CYBLE-022001-00 DC specifications (continued)

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
I _{DD27}	GPIO and reset active	–	150	–	nA	T = 25°C, V _{DD} = 3.3 V
I _{DD28}	GPIO and reset active	–	–	–		T = –40°C to 85°C
Hibernate Mode, V_{DD} = 3.6 V to 5.5 V						
I _{DD29}	GPIO and reset active	–	–	–	nA	T = 25 °C, V _{DD} = 5 V
I _{DD30}	GPIO and reset active	–	–	–		T = –40°C to 85°C
Stop Mode, V_{DD} = 1.8 V to 3.6 V						
I _{DD33}	Stop-mode current (V _{DD})	–	20	–	nA	T = 25°C, V _{DD} = 3.3 V
I _{DD34}	Stop-mode current (V _{DDR})	–	40	–		T = 25°C, V _{DDR} = 3.3 V
I _{DD35}	Stop-mode current (V _{DD})	–	–	–		T = –40°C to 85°C
I _{DD36}	Stop-mode current (V _{DDR})	–	–	–		T = –40°C to 85°C, V _{DDR} = 1.9 V to 3.6 V
Stop Mode, V_{DD} = 3.6 V to 5.5 V						
I _{DD37}	Stop-mode current (V _{DD})	–	–	–	nA	T = 25°C, V _{DD} = 5 V
I _{DD38}	Stop-mode current (V _{DDR})	–	–	–		T = 25°C, V _{DDR} = 5 V
I _{DD39}	Stop-mode current (V _{DD})	–	–	–		T = –40°C to 85°C
I _{DD40}	Stop-mode current (V _{DDR})	–	–	–		T = –40°C to 85°C

Table 10 AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
F _{CPU}	CPU frequency	DC	–	48	MHz	1.71 V ≤ V _{DD} ≤ 5.5 V
T _{SLEEP}	Wakeup from Sleep mode	–	0	–	μs	Guaranteed by characterization
T _{DEEPSLEEP}	Wakeup from Deep-Sleep mode	–	–	25		24-MHz IMO. Guaranteed by characterization
T _{HIBERNATE}	Wakeup from Hibernate mode	–	–	2	ms	Guaranteed by characterization
T _{STOP}	Wakeup from Stop mode	–	–	2		XRES wakeup

Electrical specification

6.1 GPIO

Table 11 GPIO DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
$V_{IH}^{[8]}$	Input voltage HIGH threshold	$0.7 \times V_{DD}$	–	–	V	CMOS input
	LVTTL input, $V_{DD} < 2.7\text{ V}$	$0.7 \times V_{DD}$	–	–		–
	LVTTL input, $V_{DD} \geq 2.7\text{ V}$	2.0	–	–		–
V_{IL}	Input voltage LOW threshold	–	–	$0.3 \times V_{DD}$		CMOS input
	LVTTL input, $V_{DD} < 2.7\text{ V}$	–	–	$0.3 \times V_{DD}$		–
	LVTTL input, $V_{DD} \geq 2.7\text{ V}$	–	–	0.8		–
V_{OH}	Output voltage HIGH level	$V_{DD} - 0.6$	–	–		$I_{OH} = 4\text{ mA}$ at $3.3\text{-V } V_{DD}$
	Output voltage HIGH level	$V_{DD} - 0.5$	–	–		$I_{OH} = 1\text{ mA}$ at $1.8\text{-V } V_{DD}$
V_{OL}	Output voltage LOW level	–	–	0.6		$I_{OL} = 8\text{ mA}$ at $3.3\text{-V } V_{DD}$
	Output voltage LOW level	–	–	0.6		$I_{OL} = 4\text{ mA}$ at $1.8\text{-V } V_{DD}$
	Output voltage LOW level	–	–	0.4		$I_{OL} = 3\text{ mA}$ at $3.3\text{-V } V_{DD}$
R_{PULLUP}	Pull-up resistor	3.5	5.6	8.5	k Ω	–
$R_{PULLDOWN}$	Pull-down resistor	3.5	5.6	8.5		–
I_{IL}	Input leakage current (absolute value)	–	–	2	nA	25 °C, $V_{DD} = 3.3\text{ V}$
I_{IL_CTBM}	Input leakage on CTBm input pins	–	–	4		–
C_{IN}	Input capacitance	–	–	7	pF	–
V_{HYSTTL}	Input hysteresis LVTTL	25	40	–	mV	$V_{DD} > 2.7\text{ V}$
$V_{HYSCMOS}$	Input hysteresis CMOS	$0.05 \times V_{DD}$	–	–	1	–
I_{DIODE}	Current through protection diode to V_{DD}/V_{SS}	–	–	100	μA	–
I_{TOT_GPIO}	Maximum total source or sink chip current	–	–	200	mA	–

Note

8. V_{IH} must not exceed $V_{DD} + 0.2\text{ V}$.

Electrical specification

Table 12 GPIO AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
T_{RISEF}	Rise time in Fast-Strong mode	2	–	12	ns	3.3-V V_{DD} , $C_{LOAD} = 25$ pF
T_{FALLF}	Fall time in Fast-Strong mode	2	–	12		3.3-V V_{DD} , $C_{LOAD} = 25$ pF
T_{RISES}	Rise time in Slow-Strong mode	10	–	60		3.3-V V_{DD} , $C_{LOAD} = 25$ pF
T_{FALLS}	Fall time in Slow-Strong mode	10	–	60		3.3-V V_{DD} , $C_{LOAD} = 25$ pF
$F_{GPIOOUT1}$	GPIO Fout; $3.3\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ Fast-Strong mode	–	–	33	MHz	90/10%, 25-pF load, 60/40 duty cycle
$F_{GPIOOUT2}$	GPIO Fout; $1.7\text{ V} \leq V_{DD} \leq 3.3\text{ V}$ Fast-Strong mode	–	–	16.7		90/10%, 25-pF load, 60/40 duty cycle
$F_{GPIOOUT3}$	GPIO Fout; $3.3\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ Slow-Strong mode	–	–	7		90/10%, 25-pF load, 60/40 duty cycle
$F_{GPIOOUT4}$	GPIO Fout; $1.7\text{ V} \leq V_{DD} \leq 3.3\text{ V}$ Slow-Strong mode	–	–	3.5		90/10%, 25-pF load, 60/40 duty cycle
F_{GPIOIN}	GPIO input operating frequency $1.71\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	–	–	48		90/10% V_{IO}

Table 13 OVT GPIO DC specifications (P5_0 and P5_1 Only)

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
I_{IL}	Input leakage (absolute value). $V_{IH} > V_{DD}$	–	–	10	μA	25°C , $V_{DD} = 0\text{ V}$, $V_{IH} = 3.0\text{ V}$
V_{OL}	Output voltage LOW level	–	–	0.4	V	$I_{OL} = 20\text{ mA}$, $V_{DD} > 2.9\text{ V}$

Table 14 OVT GPIO AC specifications (P5_0 and P5_1 Only)

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
T_{RISE_OVFS}	Output rise time in Fast-Strong mode	1.5	–	12	ns	25-pF load, 10%–90%, $V_{DD} = 3.3\text{ V}$
T_{FALL_OVFS}	Output fall time in Fast-Strong mode	1.5	–	12		25-pF load, 10%–90%, $V_{DD} = 3.3\text{ V}$
T_{RISESS}	Output rise time in Slow-Strong mode	10	–	60		25-pF load, 10%–90%, $V_{DD} = 3.3\text{ V}$
T_{FALLSS}	Output fall time in Slow-Strong mode	10	–	60		25-pF load, 10%–90%, $V_{DD} = 3.3\text{ V}$
$F_{GPIOOUT1}$	GPIO F_{OUT} ; $3.3\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ Fast-Strong mode	–	–	24	MHz	90/10%, 25-pF load, 60/40 duty cycle
$F_{GPIOOUT2}$	GPIO F_{OUT} ; $1.71\text{ V} \leq V_{DD} \leq 3.3\text{ V}$ Fast-Strong mode	–	–	16		90/10%, 25-pF load, 60/40 duty cycle

Electrical specification

6.2 XRES

Table 15 XRES DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
V _{IH}	Input voltage HIGH threshold	0.7 × V _{DDD}	–	–	V	CMOS input
V _{IL}	Input voltage LOW threshold	–	–	0.3 × V _{DDD}		
R _{PULLUP}	Pull-up resistor	3.5	5.6	8.5	kΩ	–
C _{IN}	Input capacitance	–	3	–	pF	–
V _{HYSXRES}	Input voltage hysteresis	–	100	–	mV	–
I _{DIODE}	Current through protection diode to V _{DD} /V _{SS}	–	–	100	μA	–

Table 16 XRES AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
T _{RESETWIDTH}	Reset pulse width	1	–	–	μs	–

6.2.1 Temperature sensor

Table 17 Temperature sensor specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
T _{SENSACC}	Temperature-sensor accuracy	–5	±1	5	°C	–40 to +85°C

6.2.2 SAR ADC

Table 18 SAR ADC DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/Conditions
A_RES	Resolution	–	–	12	bits	–
A_CHNIS_S	Number of channels - single-ended	–	–	6		6 full-speed ^[9]
A-CHNKS_D	Number of channels - differential	–	–	3		Diff inputs use neighboring I/O ^[9]
A-MONO	Monotonicity	–	–	–		Yes
A_GAINERR	Gain error	–	–	±0.1	%	With external reference
A_OFFSET	Input offset voltage	–	–	2	mV	Measured with 1-V V _{REF}
A_ISAR	Current consumption	–	–	1	mA	–
A_VINS	Input voltage range - single-ended	V _{SS}	–	V _{DDA}	V	–
A_VIND	Input voltage range - differential	V _{SS}	–	V _{DDA}		–
A_INRES	Input resistance	–	–	2.2	kΩ	–
A_INCAP	Input capacitance	–	–	10	pF	–
VREFSAR	Trimmed internal reference to SAR	–1	–	1	%	Percentage of V _{bg} (1.024 V)

Note

9. A maximum of six single-ended ADC Channels can be accomplished only if the AMUX Buses are not being used for other functionality (e.g. CapSense). If the AMUX Buses are being used for other functionality, then the

Electrical specification

Table 19 SAR ADC AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
A_PSRR	Power-supply rejection ratio	70	–	–	dB	Measured at 1-V reference
A_CMRR	Common-mode rejection ratio	66	–	–		–
A_SAMP	Sample rate	–	–	1	Msp	806 Ksp for Part Numbers devices
Fsarintref	SAR operating speed without external ref. bypass	–	–	100	Ksp	12-bit resolution
A_SNR	Signal-to-noise ratio (SNR)	65	–	–	dB	F _{IN} = 10 kHz
A_BW	Input bandwidth without aliasing	–	–	A_SAMP/2	kHz	–
A_INL	Integral nonlinearity. V _{DD} = 1.71 V to 5.5 V, 1 Msp	–1.7	–	2	LSB	V _{REF} = 1 V to V _{DD}
A_INL	Integral nonlinearity. V _{DD} = 1.71 V to 3.6 V, 1 Msp	–1.5	–	1.7		V _{REF} = 1.71 V to V _{DD}
A_INL	Integral nonlinearity. V _{DD} = 1.71 V to 5.5 V, 500 Ksp	–1.5	–	1.7		V _{REF} = 1 V to V _{DD}
A_dnl	Differential nonlinearity. V _{DD} = 1.71 V to 5.5 V, 1 Msp	–1	–	2.2		V _{REF} = 1 V to V _{DD}
A_DNL	Differential nonlinearity. V _{DD} = 1.71 V to 3.6 V, 1 Msp	–1	–	2		V _{REF} = 1.71 V to V _{DD}
A_DNL	Differential nonlinearity. V _{DD} = 1.71 V to 5.5 V, 500 Ksp	–1	–	2.2		V _{REF} = 1 V to V _{DD}
A_THD	Total harmonic distortion	–	–	–65	dB	F _{IN} = 10 kHz

Electrical specification

6.2.3 CSD

Table 20 CSD block specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
V _{CSD}	Voltage range of operation	1.71	–	5.5	V	–
IDAC1	DNL for 8-bit resolution	–1	–	1	LSB	–
IDAC1	INL for 8-bit resolution	–3	–	3		–
IDAC2	DNL for 7-bit resolution	–1	–	1		–
IDAC2	INL for 7-bit resolution	–3	–	3		–
SNR	Ratio of counts of finger to noise	5	–	–	Ratio	Capacitance range of 9 pF to 35 pF, 0.1-pF sensitivity. Radio is not operating during the scan
I _{DAC1_CRT1}	Output current of IDAC1 (8 bits) in High range	–	612	–	μA	–
I _{DAC1_CRT2}	Output current of IDAC1 (8 bits) in Low range	–	306	–		–
I _{DAC2_CRT1}	Output current of IDAC2 (7 bits) in High range	–	305	–		–
I _{DAC2_CRT2}	Output current of IDAC2 (7 bits) in Low range	–	153	–		–

6.3 Digital peripherals

6.3.1 Timer

Table 21 Timer DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
I _{TIM1}	Block current consumption at 3 MHz	–	–	42	μA	16-bit timer
I _{TIM2}	Block current consumption at 12 MHz	–	–	130		
I _{TIM3}	Block current consumption at 48 MHz	–	–	535		

Table 22 Timer AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
T _{TIMFREQ}	Operating frequency	F _{CLK}	–	48	MHz	–
T _{CAPWINT}	Capture pulse width (internal)	2 × T _{CLK}	–	–	ns	–
T _{CAPWEXT}	Capture pulse width (external)	2 × T _{CLK}	–	–		–
T _{TIMRES}	Timer resolution	T _{CLK}	–	–		–
T _{TENWIDINT}	Enable pulse width (internal)	2 × T _{CLK}	–	–		–
T _{TENWIDEXT}	Enable pulse width (external)	2 × T _{CLK}	–	–		–
T _{TIMRESWINT}	Reset pulse width (internal)	2 × T _{CLK}	–	–		–
T _{TIMREEXT}	Reset pulse width (external)	2 × T _{CLK}	–	–		–

Electrical specification

6.3.2 Counter

Table 23 Counter DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
I _{CTR1}	Block current consumption at 3 MHz	–	–	42	μA	16-bit counter
I _{CTR2}	Block current consumption at 12 MHz	–	–	130		
I _{CTR3}	Block current consumption at 48 MHz	–	–	535		

Table 24 Counter AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
T _{CTRFREQ}	Operating frequency	F _{CLK}	–	48	MHz	–
T _{CTRPWINT}	Capture pulse width (internal)	2 × T _{CLK}	–	–	ns	–
T _{CTRPWEXT}	Capture pulse width (external)	2 × T _{CLK}	–	–		–
T _{CTRES}	Counter Resolution	T _{CLK}	–	–		–
T _{CENWIDINT}	Enable pulse width (internal)	2 × T _{CLK}	–	–		–
T _{CENWIDEXT}	Enable pulse width (external)	2 × T _{CLK}	–	–		–
T _{CTRRESWINT}	Reset pulse width (internal)	2 × T _{CLK}	–	–		–
T _{CTRRESWEXT}	Reset pulse width (external)	2 × T _{CLK}	–	–		–

Electrical specification

6.3.3 Pulse Width Modulation (PWM)

Table 25 PWM DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
I_{PWM1}	Block current consumption at 3 MHz	–	–	42	μA	16-bit PWM
I_{PWM2}	Block current consumption at 12 MHz	–	–	130		
I_{PWM3}	Block current consumption at 48 MHz	–	–	535		

Table 26 PWM AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
$T_{PWMFREQ}$	Operating frequency	F_{CLK}	–	48	MHz	–
$T_{PWMPWINT}$	Pulse width (internal)	$2 \times T_{CLK}$	–	–	ns	–
T_{PWMEXT}	Pulse width (external)	$2 \times T_{CLK}$	–	–		–
$T_{PWMKILLINT}$	Kill pulse width (internal)	$2 \times T_{CLK}$	–	–		–
$T_{PWMKILLEXT}$	Kill pulse width (external)	$2 \times T_{CLK}$	–	–		–
$T_{PWMEINT}$	Enable pulse width (internal)	$2 \times T_{CLK}$	–	–		–
$T_{PWMEEXT}$	Enable pulse width (external)	$2 \times T_{CLK}$	–	–		–
$T_{PWMRESWINT}$	Reset pulse width (internal)	$2 \times T_{CLK}$	–	–		–
$T_{PWMRESWEXT}$	Reset pulse width (external)	$2 \times T_{CLK}$	–	–		–

6.3.4 LCD direct drive

Table 27 LCD direct drive DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
I_{LCDLOW}	Operating current in low-power mode	–	17.5	–	μA	16 × 4 small segment display at 50 Hz
C_{LCDCAP}	LCD capacitance per segment/common driver	–	500	5000	pF	–
LCD_{OFFSET}	Long-term segment offset	–	20	–	mV	–
I_{LCDOP1}	LCD system operating current $V_{BIAS} = 5 V$	–	2	–	mA	32 × 4 segments. 50 Hz at 25°C
I_{LCDOP2}	LCD system operating current $V_{BIAS} = 3.3 V$	–	2	–		32 × 4 segments 50 Hz at 25°C

Table 28 LCD Direct Drive AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
F_{LCD}	LCD frame rate	10	50	150	Hz	–

Electrical specification

6.4 Serial communication

Table 29 Fixed I²C DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
I _{I2C1}	Block current consumption at 100 kHz	–	–	50	μA	–
I _{I2C2}	Block current consumption at 400 kHz	–	–	155		–
I _{I2C3}	Block current consumption at 1 Mbps	–	–	390		–
I _{I2C4}	I ² C enabled in Deep-Sleep mode	–	–	1.4		–

Table 30 Fixed I²C AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
F _{I2C1}	Bit rate	–	–	400	kHz	–

Table 31 Fixed UART DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
I _{UART1}	Block current consumption at 100 kbps	–	–	55	μA	–
I _{UART2}	Block current consumption at 1000 kbps	–	–	312		–

Table 32 Fixed UART AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
F _{UART}	Bit rate	–	–	1	Mbps	–

Table 33 Fixed SPI DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
I _{SPI1}	Block current consumption at 1 Mbps	–	–	360	μA	–
I _{SPI2}	Block current consumption at 4 Mbps	–	–	560		–
I _{SPI3}	Block current consumption at 8 Mbps	–	–	600		–

6.5 Memory

Table 34 Flash DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
V _{PE}	Erase and program voltage	1.71	–	5.5	V	–
T _{WS48}	Number of Wait states at 32–48 MHz	2	–	–		CPU execution from flash
T _{WS32}	Number of Wait states at 16–32 MHz	1	–	–		CPU execution from flash
T _{WS16}	Number of Wait states for 0–16 MHz	0	–	–		CPU execution from flash

Electrical specification

Table 35 Flash AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
$T_{\text{ROWWRITE}}^{[10]}$	Row (block) write time (erase and program)	–	–	20	ms	Row (block) = 128 bytes
$T_{\text{ROWERASE}}^{[10]}$	Row erase time	–	–	13		–
$T_{\text{ROWPROGRAM}}^{[10]}$	Row program time after erase	–	–	7		–
$T_{\text{BULKERASE}}^{[10]}$	Bulk erase time (128 KB)	–	–	35		–
$T_{\text{DEVPROG}}^{[10]}$	Total device program time	–	–	25	seconds	–
F_{END}	Flash endurance	100 K	–	–	cycles	–
F_{RET}	Flash retention. $T_A \leq 55^\circ\text{C}$, 100 K P/E cycles	20	–	–	years	–
F_{RET2}	Flash retention. $T_A \leq 85^\circ\text{C}$, 10 K P/E cycles	10	–	–		–

6.6 System resources

6.6.1 Power-On-Reset (POR)

Table 36 POR DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
V_{RISEIPOR}	Rising trip voltage	0.80	–	1.45	V	–
V_{FALLIPOR}	Falling trip voltage	0.75	–	1.40		–
V_{IPORHYST}	Hysteresis	15	–	200	mV	–

Table 37 POR AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
$TPPOR_TR$	Precision power-on reset (PPOR) response time in Active and Sleep modes	–	–	1	μs	–

Table 38 Brown-out detect

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
V_{FALLPPOR}	BOD trip voltage in Active and Sleep modes	1.64	–	–	V	–
$V_{\text{FALLDPSLP}}$	BOD trip voltage in Deep Sleep	1.4	–	–		–

Table 39 Hibernate reset

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
V_{HBRTRIP}	BOD trip voltage in Hibernate	1.1	–	–	V	–

Note

10. It can take as much as 20 ms to write to flash. During this time, the device should not be reset, or flash operations will be interrupted and cannot be relied on to have completed. Reset sources include the XRES pin, software resets, CPU lockup states and privilege violations, improper power supply levels, and watch-dogs. Make certain that these are not inadvertently activated.

Electrical specification

6.6.2 Voltage monitors (LVD)

Table 40 Voltage monitor DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
V _{LVI1}	LVI_A/D_SEL[3:0] = 0000b	1.71	1.75	1.79	V	–
V _{LVI2}	LVI_A/D_SEL[3:0] = 0001b	1.76	1.80	1.85		–
V _{LVI3}	LVI_A/D_SEL[3:0] = 0010b	1.85	1.90	1.95		–
V _{LVI4}	LVI_A/D_SEL[3:0] = 0011b	1.95	2.00	2.05		–
V _{LVI5}	LVI_A/D_SEL[3:0] = 0100b	2.05	2.10	2.15		–
V _{LVI6}	LVI_A/D_SEL[3:0] = 0101b	2.15	2.20	2.26		–
V _{LVI7}	LVI_A/D_SEL[3:0] = 0110b	2.24	2.30	2.36		–
V _{LVI8}	LVI_A/D_SEL[3:0] = 0111b	2.34	2.40	2.46		–
V _{LVI9}	LVI_A/D_SEL[3:0] = 1000b	2.44	2.50	2.56		–
V _{LVI10}	LVI_A/D_SEL[3:0] = 1001b	2.54	2.60	2.67		–
V _{LVI11}	LVI_A/D_SEL[3:0] = 1010b	2.63	2.70	2.77		–
V _{LVI12}	LVI_A/D_SEL[3:0] = 1011b	2.73	2.80	2.87		–
V _{LVI13}	LVI_A/D_SEL[3:0] = 1100b	2.83	2.90	2.97		–
V _{LVI14}	LVI_A/D_SEL[3:0] = 1101b	2.93	3.00	3.08		–
V _{LVI15}	LVI_A/D_SEL[3:0] = 1110b	3.12	3.20	3.28		–
V _{LVI16}	LVI_A/D_SEL[3:0] = 1111b	4.39	4.50	4.61		–
LVI_IDD	Block current	–	–	100	μA	–

Table 41 Voltage monitor AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
T _{MONTRIP}	Voltage monitor trip time	–	–	1	μs	–

6.6.3 SWD interface

Table 42 SWD interface specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
F _{SWDCLK1}	$3.3\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	–	–	14	MHz	SWDCLK ≤ 1/3 CPU clock frequency
F _{SWDCLK2}	$1.71\text{ V} \leq V_{DD} \leq 3.3\text{ V}$	–	–	7		
T _{SWDI_SETUP}	T = 1/f SWDCLK	0.25 × T	–	–	ns	–
T _{SWDI_HOLD}	T = 1/f SWDCLK	0.25 × T	–	–		–
T _{SWDO_VALID}	T = 1/f SWDCLK	–	–	0.5 × T		–
T _{SWDO_HOLD}	T = 1/f SWDCLK	1	–	–		–

Electrical specification

6.6.4 Internal main oscillator

Table 43 IMO DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
I _{IMO1}	IMO operating current at 48 MHz	–	–	1000	μA	–
I _{IMO2}	IMO operating current at 24 MHz	–	–	325		–
I _{IMO3}	IMO operating current at 12 MHz	–	–	225		–
I _{IMO4}	IMO operating current at 6 MHz	–	–	180		–
I _{IMO5}	IMO operating current at 3 MHz	–	–	150		–

Table 44 IMO AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
F _{IMOTOL3}	Frequency variation from 3 to 48 MHz	–	–	±2	%	With API-called calibration
F _{IMOTOL3}	IMO startup time	–	12	–	μs	–

6.6.5 Internal low-speed oscillator

Table 45 ILO DC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
I _{ILO2}	ILO operating current at 32 kHz	–	0.3	1.05	μA	–

Table 46 ILO AC specifications

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
T _{STARTILO1}	ILO startup time	–	–	2	ms	–
F _{ILOTRIM1}	32-kHz trimmed frequency	15	32	50	kHz	–

Table 47 Recommended ECO trim value

Parameter	Description	Value	Details/conditions
ECO _{TRIM}	24-MHz trim value (firmware configuration)	0x00009898	Recommended trim value that needs to be loaded to register CY_SYS_XTAL_BLERD_BB_XO_CAP-TRIM_REG

6.6.6 Bluetooth® LE subsystem

Table 48 Bluetooth® LE subsystem

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
RF Receiver specification						
RXS, IDLE	RX sensitivity with idle transmitter	–	–89	–	dBm	–
	RX sensitivity with idle transmitter excluding Balun loss	–	–91	–		Guaranteed by design simulation
RXS, DIRTY	RX sensitivity with dirty transmitter	–	–87	–70		RF-PHY Specification (RCV-LE/CA/01/C)
RXS, HIGHGAIN	RX sensitivity in high-gain mode with idle transmitter	–	–91	–		–
PRXMAX	Maximum input power	–10	–1	–		RF-PHY Specification (RCV-LE/CA/06/C)

Electrical specification

Table 48 Bluetooth® LE subsystem (continued)

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
CI1	Cochannel interference, Wanted signal at –67 dBm and Interferer at FRX	–	9	21	dB	RF-PHY Specification (RCV-LE/CA/03/C)
CI2	Adjacent channel interference Wanted signal at –67 dBm and Interferer at FRX ±1 MHz	–	3	15	dB	RF-PHY Specification (RCV-LE/CA/03/C)
CI3	Adjacent channel interference Wanted signal at –67 dBm and Interferer at FRX ±2 MHz	–	–29	–		RF-PHY Specification (RCV-LE/CA/03/C)
CI4	Adjacent channel interference Wanted signal at –67 dBm and Interferer at ≥FRX ±3 MHz	–	–39	–		RF-PHY Specification (RCV-LE/CA/03/C)
CI5	Adjacent channel interference Wanted Signal at –67 dBm and Interferer at Image frequency (F _{IMAGE})	–	–20	–		RF-PHY Specification (RCV-LE/CA/03/C)
CI3	Adjacent channel interference Wanted signal at –67 dBm and Interferer at Image frequency (F _{IMAGE} ± 1 MHz)	–	–30	–		RF-PHY Specification (RCV-LE/CA/03/C)
OBB1	Out-of-band blocking, Wanted signal at –67 dBm and Interferer at F = 30–2000 MHz	–30	–27	–	dBm	RF-PHY Specification (RCV-LE/CA/04/C)
OBB2	Out-of-band blocking, Wanted signal at –67 dBm and Interferer at F = 2003–2399 MHz	–35	–27	–		RF-PHY Specification (RCV-LE/CA/04/C)
OBB3	Out-of-band blocking, Wanted signal at –67 dBm and Interferer at F = 2484–2997 MHz	–35	–27	–		RF-PHY Specification (RCV-LE/CA/04/C)
OBB4	Out-of-band blocking, Wanted signal a –67 dBm and Interferer at F = 3000–12750 MHz	–30	–27	–		RF-PHY Specification (RCV-LE/CA/04/C)
IMD	Intermodulation performance Wanted signal at –64 dBm and 1-Mbps Bluetooth® LE, third, fourth, and fifth offset channel	–50	–	–		RF-PHY Specification (RCV-LE/CA/05/C)
RXSE1	Receiver spurious emission 30 MHz to 1.0 GHz	–	–	–57		100-kHz measurement bandwidth ETSI EN300 328 V1.8.1
RXSE2	Receiver spurious emission 1.0 GHz to 12.75 GHz	–	–	–47		1-MHz measurement bandwidth ETSI EN300 328 V1.8.1
RF transmitter specifications						
TXP, ACC	RF power accuracy	–	±1	–	dB	–
TXP, RANGE	RF power control range	–	20	–		–

Electrical specification

Table 48 Bluetooth® LE subsystem (continued)

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
TXP, 0dBm	Output power, 0-dB Gain setting (PA7)	–	0	–	dBm	–
TXP, MAX	Output power, maximum power setting (PA10)	–	3	–		–
TXP, MIN	Output power, minimum power setting (PA1)	–	–18	–		–
F2AVG	Average frequency deviation for 10101010 pattern	185	–	–	kHz	RF-PHY Specification (TRM-LE/CA/05/C)
F1AVG	Average frequency deviation for 11110000 pattern	225	250	275		RF-PHY Specification (TRM-LE/CA/05/C)
EO	Eye opening = $\Delta F2AVG/\Delta F1AVG$	0.8	–	–		RF-PHY Specification (TRM-LE/CA/05/C)
FTX, ACC	Frequency accuracy	–150	–	150	kHz	RF-PHY Specification (TRM-LE/CA/06/C)
FTX, MAXDR	Maximum frequency drift	–50	–	50		RF-PHY Specification (TRM-LE/CA/06/C)
FTX, INITDR	Initial frequency drift	–20	–	20		RF-PHY Specification (TRM-LE/CA/06/C)
FTX, DR	Maximum drift rate	–20	–	20	kHz/ 50 μ s	RF-PHY Specification (TRM-LE/CA/06/C)
IBSE1	In-band spurious emission at 2-MHz offset	–	–	–20	dBm	RF-PHY Specification (TRM-LE/CA/03/C)
IBSE2	In-band spurious emission at ≥ 3 -MHz offset	–	–	–30		RF-PHY Specification (TRM-LE/CA/03/C)
TXSE1	Transmitter spurious emissions (average), <1.0 GHz	–	–	–55.5		FCC-15.247
TXSE2	Transmitter spurious emissions (average), >1.0 GHz	–	–	–41.5		FCC-15.247

RF current specifications

IRX	Receive current in normal mode	–	18.7	–	mA	–
IRX_RF	Radio receive current in normal mode	–	16.4	–		Measured at V_{DDR}
IRX, HIGHGAIN	Receive current in high-gain mode	–	21.5	–		–
ITX, 3dBm	TX current at 3-dBm setting (PA10)	–	20	–		–
ITX, 0dBm	TX current at 0-dBm setting (PA7)	–	16.5	–		–
ITX_RF, 0dBm	Radio TX current at 0 dBm setting (PA7)	–	15.6	–		Measured at V_{DDR}
ITX_RF, 0dBm	Radio TX current at 0 dBm excluding Balun loss	–	14.2	–		Guaranteed by design simulation
ITX, –3dBm	TX current at –3-dBm setting (PA4)	–	15.5	–		–
ITX, –6dBm	TX current at –6-dBm setting (PA3)	–	14.5	–		–
ITX, –12dBm	TX current at –12-dBm setting (PA2)	–	13.2	–		–
ITX, –18dBm	TX current at –18-dBm setting (PA1)	–	12.5	–		–

Electrical specification

Table 48 Bluetooth® LE subsystem (continued)

Parameter	Description	Min	Typ	Max	Unit	Details/conditions
lavg_1sec, 0dBm	Average current at 1-second Bluetooth® LE connection interval	–	17.1	–	μA	TXP: 0 dBm; ±20-ppm master and slave clock accuracy. For empty PDU exchange
lavg_4sec, 0dBm	Average current at 4-second Bluetooth® LE connection interval	–	6.1	–		TXP: 0 dBm; ±20-ppm master and slave clock accuracy. For empty PDU exchange

General RF specifications

FREQ	RF operating frequency	2400	–	2482	MHz	–
CHBW	Channel spacing	–	2	–		–
DR	On-air data rate	–	1000	–	kbps	–
IDLE2TX	Bluetooth® LE.IDLE to Bluetooth® LE. TX transition time	–	120	140	μs	–
IDLE2RX	Bluetooth® LE.IDLE to Bluetooth® LE. RX transition time	–	75	120		–

RSSI specifications

RSSI, ACC	RSSI accuracy	–	±5	–	dB	–
RSSI, RES	RSSI resolution	–	1	–		–
RSSI, PER	RSSI sample period	–	6	–	μs	–

7 Environmental specifications

7.1 Environmental compliance

This Infineon Bluetooth® LE module is built in compliance with the Restriction of Hazardous Substances (RoHS) and Halogen Free (HF) directives. The Infineon module and components used to produce this module are RoHS and HF compliant.

7.2 RF certification

The CYBLE-022001-00 module is certified under the following RF certification standards:

- FCC: WAP2001
- CE
- IC: 7922A-2001
- MIC: 005-101007
- KC: MSIP-CRM-Cyp-2001

7.3 Safety certification

The CYBLE-022001-00 module complies with the following safety regulations:

- Underwriters Laboratories, Inc. (UL): Filing E331901
- CSA
- TUV

7.4 Environmental conditions

Table 49 describes the operating and storage conditions for the Infineon Bluetooth® LE module.

Table 49 Environmental conditions for CYBLE-022001-00

Description	Minimum specification	Maximum specification
Operating temperature	–40°C	85°C
Operating humidity (relative, non-condensation)	5%	85%
Thermal ramp rate	–	3°C/minute
Storage temperature	–40°C	85°C
Storage temperature and humidity	–	85°C at 85%
ESD: Module integrated into system Components ^[11]	–	15 kV Air 2.2 kV Contact

7.5 ESD and EMI protection

Exposed components require special attention to ESD and electromagnetic interference (EMI).

A grounded conductive layer inside the device enclosure is suggested for EMI and ESD performance. Any openings in the enclosure near the module should be surrounded by a grounded conductive layer to provide ESD protection and a low-impedance path to ground.

Device handling: Proper ESD protocol must be followed in manufacturing to ensure component reliability.

Note

- 11.T This does not apply to the RF pins (ANT, XTALI, and XTALO). RF pins (ANT, XTALI, and XTALO) are tested for 500-V HBM.

8 Regulatory information

8.1 FCC

FCC NOTICE:

The device CYBLE-022001-00, including the antenna 2450AT18B100 from Johanson Technology, complies with Part 15 of the FCC Rules. The device meets the requirements for modular transmitter approval as detailed in FCC public Notice DA00-1407. transmitter Operation is subject to the following two conditions: (1) This device may not cause harmful interference, and (2) This device must accept any interference received, including interference that may cause undesired operation.

CAUTION:

The FCC requires the user to be notified that any changes or modifications made to this device that are not expressly approved by Infineon Semiconductor may void the user's authority to operate the equipment.

This equipment has been tested and found to comply with the limits for a Class B digital device, pursuant to Part 15 of the FCC Rules. These limits are designed to provide reasonable protection against harmful interference in a residential installation. This equipment generates uses and can radiate radio frequency energy and, if not installed and used in accordance with the instructions, may cause harmful interference to radio communications. However, there is no guarantee that interference will not occur in a particular installation. If this equipment does cause harmful interference to radio or television reception, which can be determined by turning the equipment off and on, the user is encouraged to try to correct the interference by one or more of the following measures:

- Reorient or relocate the receiving antenna.
- Increase the separation between the equipment and receiver.
- Connect the equipment into an outlet on a circuit different from that to which the receiver is connected.
- Consult the dealer or an experienced radio/TV technician for help

LABELING REQUIREMENTS:

The Original Equipment Manufacturer (OEM) must ensure that FCC labelling requirements are met. This includes a clearly visible label on the outside of the OEM enclosure specifying the appropriate Infineon Semiconductor FCC identifier for this product as well as the FCC Notice above. The FCC identifier is FCC ID: WAP2001.

In any case the end product must be labeled exterior with "Contains FCC ID: WAP2001"

ANTENNA WARNING:

This device is tested with a standard SMA connector and with the antennas listed below. When integrated in the OEMs product, these fixed antennas require installation preventing end-users from replacing them with non-approved antennas. Any antenna not in the following table must be tested to comply with FCC Section 15.203 for unique antenna connectors and Section 15.247 for emissions.

RF EXPOSURE:

To comply with FCC RF Exposure requirements, the Original Equipment Manufacturer (OEM) must ensure to install the approved antenna in the previous.

The preceding statement must be included as a CAUTION statement in manuals, for products operating with the approved antennas in [Table 6](#), to alert users on FCC RF Exposure compliance. Any notification to the end user of installation or removal instructions about the integrated radio module is not allowed.

The radiated output power of CYBLE-022001-00 with the chip antenna mounted (FCC ID: WAP2001) is far below the FCC radio frequency exposure limits. Nevertheless, use CYBLE-022001-00 in such a manner that minimizes the potential for human contact during normal operation.

End users may not be provided with the module installation instructions. OEM integrators and end users must be provided with transmitter operating conditions for satisfying RF exposure compliance.

8.2 ISED

Innovation, Science and Economic Development Canada (ISED) certification

CYBLE-022001-00 is licensed to meet the regulatory requirements of Innovation, Science and Economic Development Canada (ISED).

License: IC: 7922A-2001

Manufacturers of mobile, fixed or portable devices incorporating this module are advised to clarify any regulatory questions and ensure compliance for SAR and/or RF exposure limits. Users can obtain Canadian information on RF exposure and compliance from www.ic.gc.ca.

This device has been designed to operate with the antennas listed in **Table 6**, having a maximum gain of 0.5 dBi. Antennas not included in this list or having a gain greater than 0.5 dBi are strictly prohibited for use with this device. The required antenna impedance is 50 ohms. The antenna used for this transmitter must not be co-located or operating in conjunction with any other antenna or transmitter.

ISED NOTICE:

The device CYBLE-022001-00 including the antenna 2450AT18B100 from Johanson technology, complies with Canada RSS-GEN Rules. The device meets the requirements for modular transmitter approval as detailed in RSS-GEN. Operation is subject to the following two conditions: (1) This device may not cause harmful interference, and (2) This device must accept any interference received, including interference that may cause undesired operation.

ISED RADIATION EXPOSURE STATEMENT FOR CANADA

This device complies with Innovation, Science and Economic Development (ISED) Canada licence-exempt RSS standard(s). Operation is subject to the following two conditions: (1) this device may not cause interference, and (2) this device must accept any interference, including interference that may cause undesired operation of the device.

Cet appareil est conforme à la norme sur l'innovation, la science et le développement économique (ISED) norme RSS exempte de licence. L'exploitation est autorisée aux deux conditions suivantes: (1) l'appareil ne doit pas produire de brouillage, et (2) l'utilisateur de l'appareil doit accepter tout brouillage radioélectrique subi, même si le brouillage est susceptible d'en compromettre le fonctionnement.

LABELING REQUIREMENTS:

The Original Equipment Manufacturer (OEM) must ensure that ISED labelling requirements are met. This includes a clearly visible label on the outside of the OEM enclosure specifying the appropriate Infineon Semiconductor IC identifier for this product as well as the ISED Notice above. The IC identifier is 7922A-2001. In any case, the end product must be labeled in its exterior with "Contains IC: 7922A-2001"

8.3 European R&TTE declaration of conformity

Hereby, Infineon Semiconductor declares that the Bluetooth® module CYBLE-022001-00 complies with the essential requirements and other relevant provisions of Directive 2014/53/EU. As a result of the conformity assessment procedure described in Annex III of the Directive 1999/5/EC, the end-customer equipment should be labeled as follows:

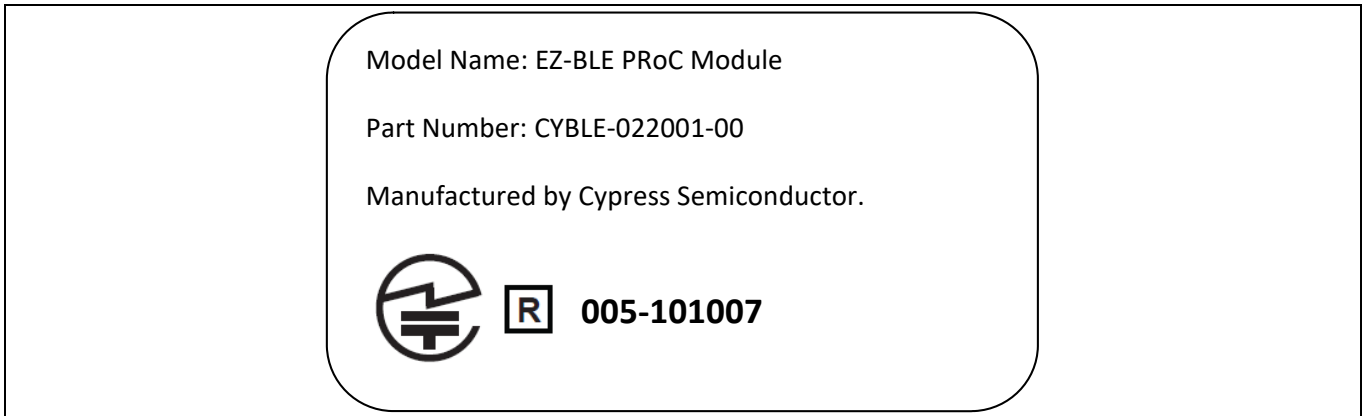


All versions of the CYBLE-022001-00 in the specified reference design can be used in the following countries: Austria, Belgium, Cyprus, Czech Republic, Denmark, Estonia, Finland, France, Germany, Greece, Hungary, Ireland, Italy, Latvia, Lithuania, Luxembourg, Malta, Poland, Portugal, Slovakia, Slovenia, Spain, Sweden, The Netherlands, the United Kingdom, Switzerland, and Norway.

8.4 MIC Japan

CYBLE-022001-00 is certified as a module with type certification number 005-101007. End products that integrate CYBLE-022001-00 do not need additional MIC Japan certification for the end product.

End product can display the certification label of the embedded module.



8.5 KC Korea

CYBLE-022001-00 is certified for use in Korea with certificate number MSIP-CRM-Cyp-2001.

한국 인증 세부정보:



1. 제품명(모델명): 특정소출력무선기기(무선데이터통신시스템용 무선기기), CYBLE-022001-00
2. 인증 번호: MSIP-CRM-Cyp-2001
3. 라이선스 소유자: Cypress Semiconductor Corporation
4. 제조일자: 2015.04
5. 제조업체/국가명: Cypress Semiconductor Corporation/ 중국

해당 무선설비는 전파혼신 가능성이 있으므로 인명안전과 관련된 서비스는 할 수 없습니다.

9 Packaging

Table 50 Solder reflow peak temperature

Module part number	Package	Maximum peak temperature	Maximum time at peak temperature	No. of cycles
CYBLE-022001-00	21-pad SMT	260°C	30 seconds	2

Table 51 Package Moisture Sensitivity Level (MSL), IPC/JEDEC J-STD-2

Module part number	Package	MSL
CYBLE-022001-00	21-pad SMT	MSL 3

The CYBLE-022001-00 is offered in tape and reel packaging. [Figure 10](#) details the tape dimensions used for the CYBLE-022001-00.

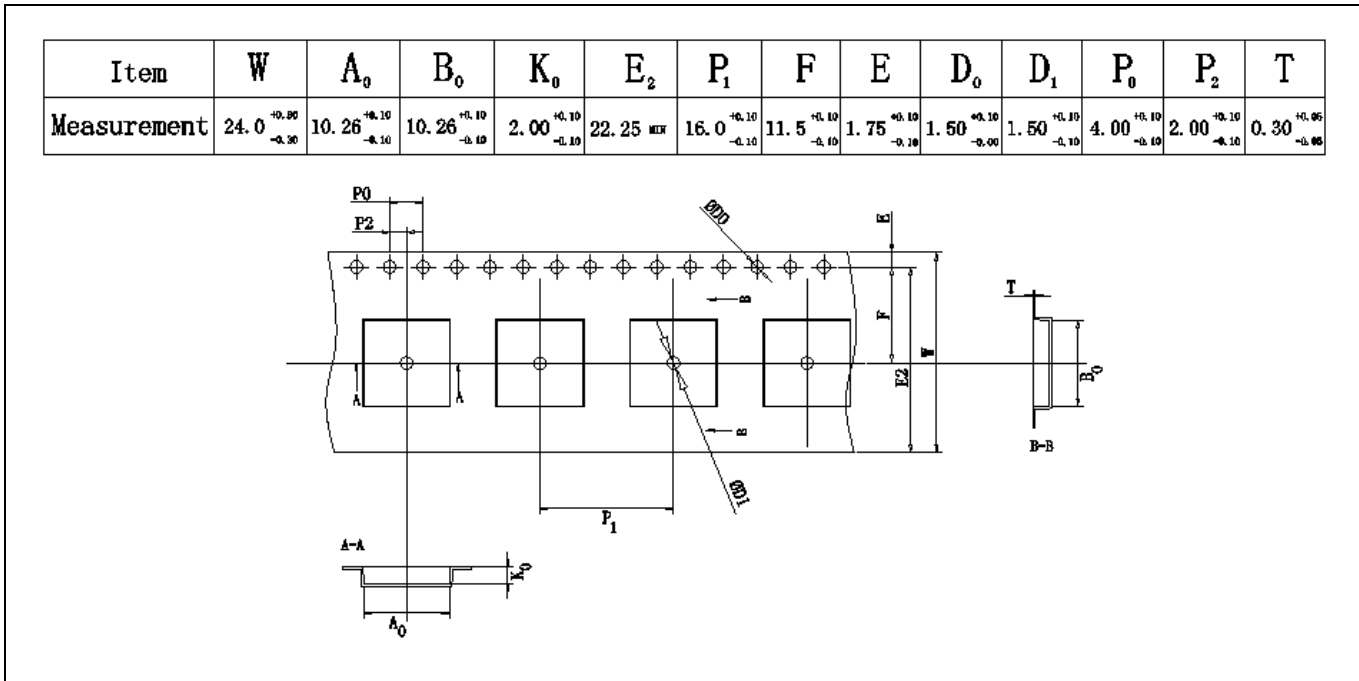


Figure 10 CYBLE-022001-00 tape dimensions

[Figure 11](#) details the orientation of the CYBLE-022001-00 in the tape as well as the direction for unreeling.

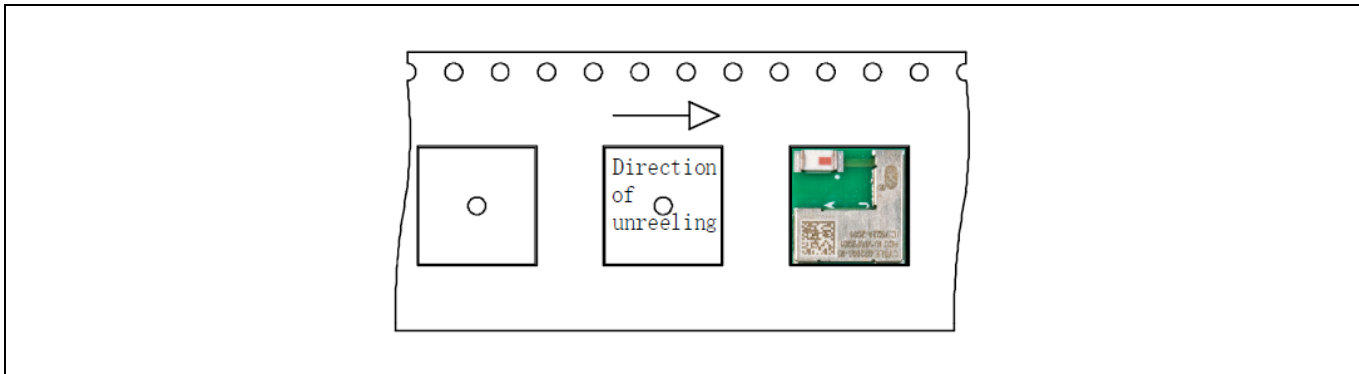


Figure 11 Component orientation in tape and unreeling direction

Figure 12 details reel dimensions used for the CYBLE-022001-00.

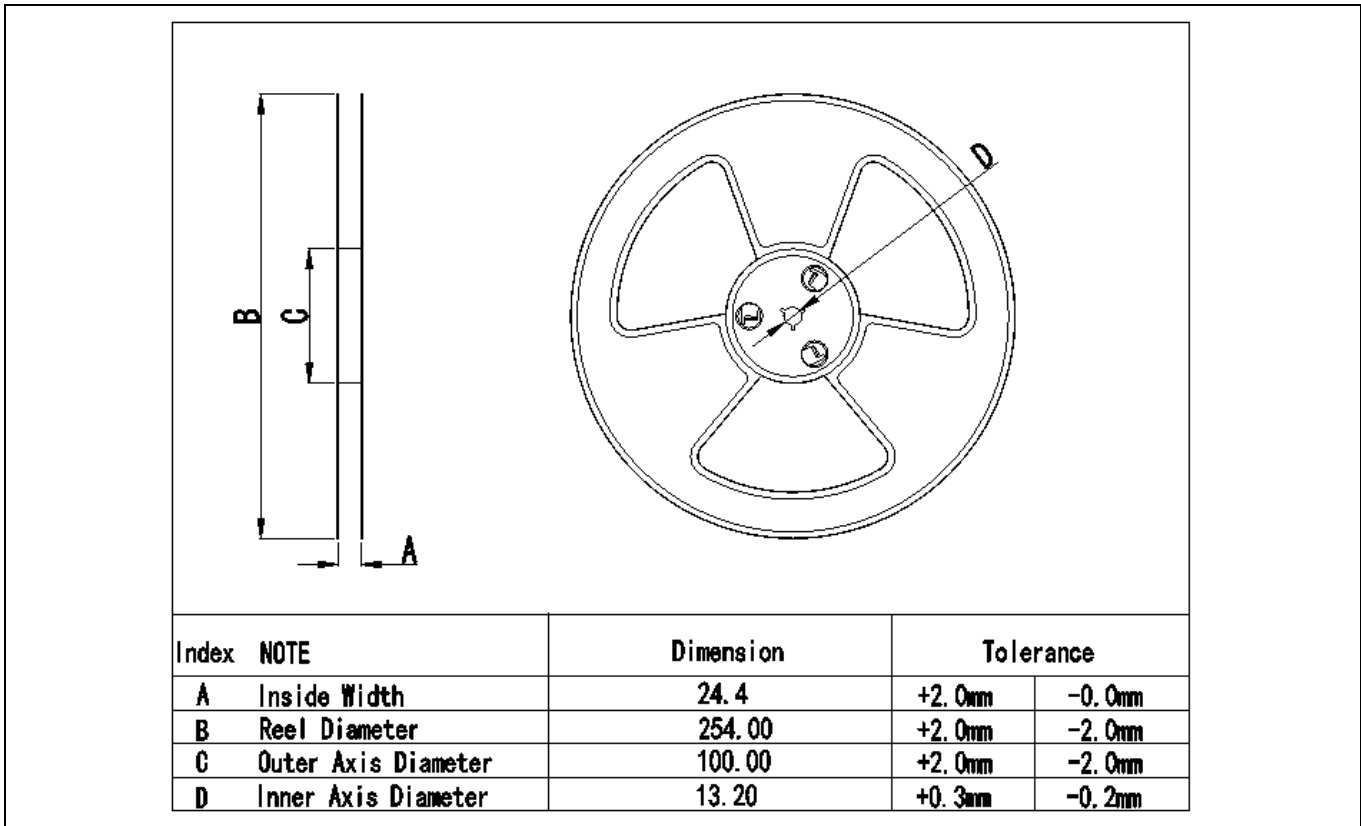


Figure 12 Reel dimensions

The CYBLE-022001-00 is designed to be used with pick-and-place equipment in an SMT manufacturing environment. The center-of-mass for the CYBLE-022001-00 is detailed in [Figure 13](#).

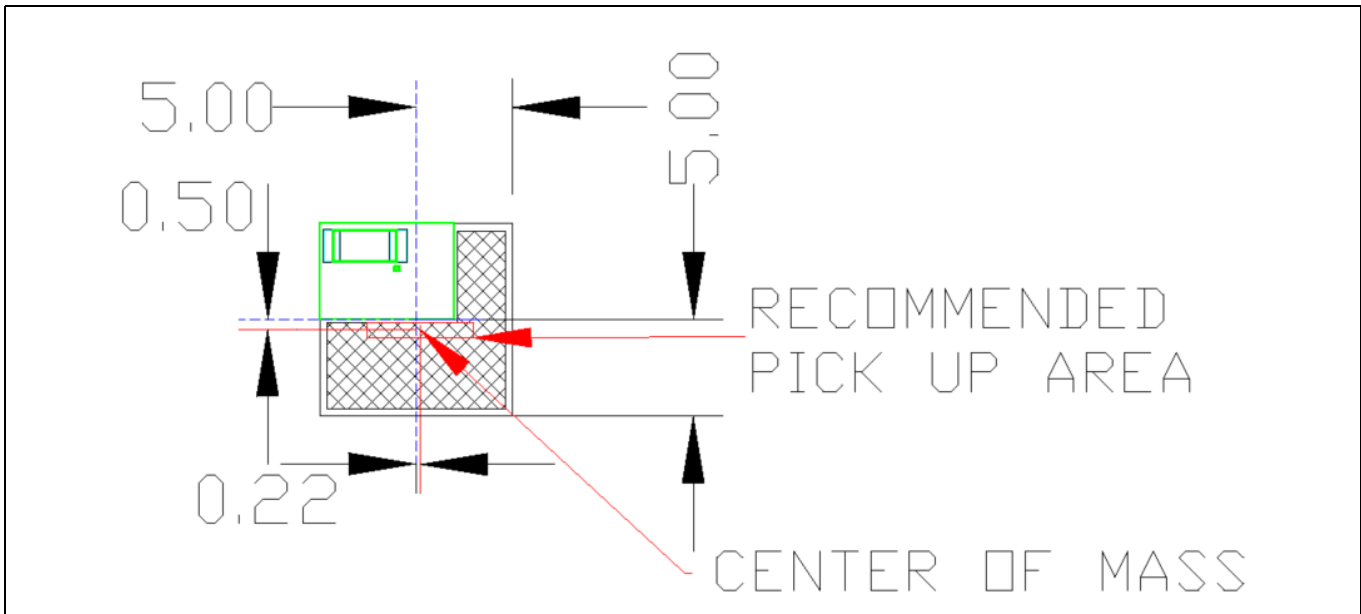


Figure 13 CYBLE-022001-00 center of mass

10 Ordering information

Table 52 lists the CYBLE-022001-00 part number and features. **Table 53** lists the reel shipment quantities for the CYBLE-022001-00.

Table 52 Ordering information

Part number	CPU Speed (MHz)	Flash Size (KB)	CapSense™	SCB	TCPWM	12-bit SAR ADC	I ² S	LCD	Package	Packing
CYBLE-022001-00	48	128	Yes	2	4	1 Msps	Yes	Yes	21-SMT	Tape and Reel

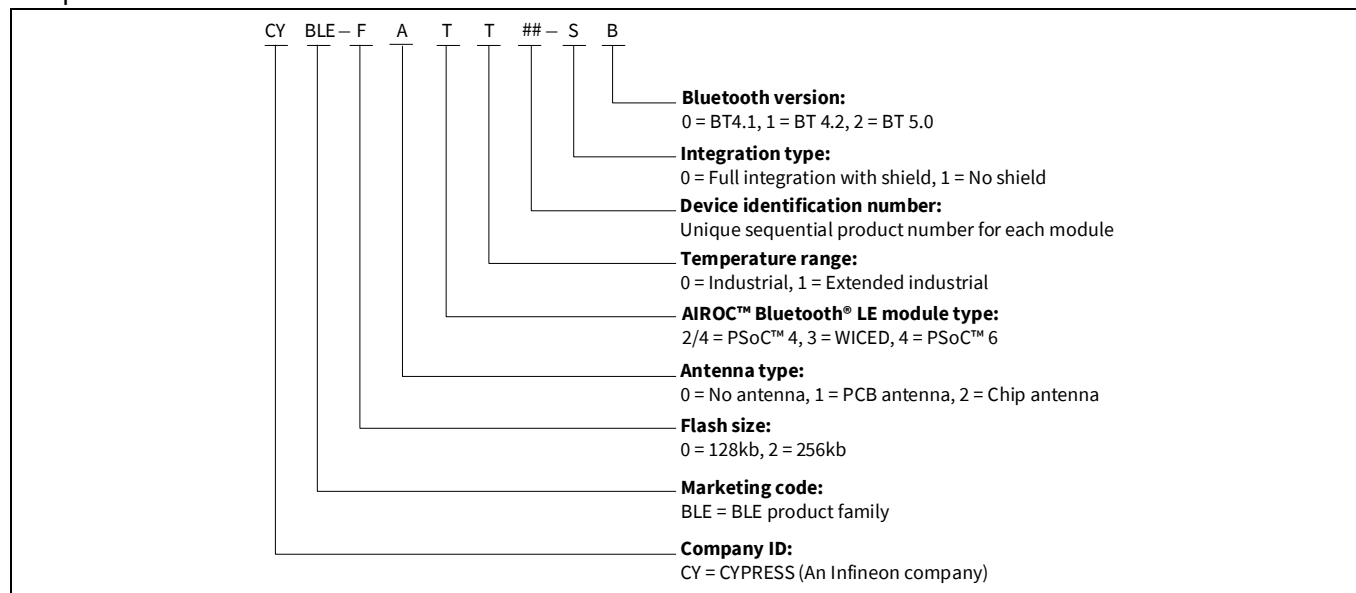
Table 53 Tape and reel package quantity and minimum order amount

Description	Minimum reel quantity	Maximum reel quantity	Comments
Reel Quantity	500	500	Ships in 500 unit reel quantities.
Minimum Order Quantity (MOQ)	500	–	–
Order Increment (OI)	500	–	–

The CYBLE-022001-00 is offered in tape and reel packaging. The CYBLE-022001-00 ships with a maximum of 500 units/reel.

10.1 Part numbering convention

The part numbers are of the form CYBLE-FATT##-SB where the fields are defined as follows.



For additional information and a complete list of Infineon Semiconductor Bluetooth® LE products, contact your local Infineon sales representative. To locate the nearest Infineon office, visit our website.

U.S. Infineon Headquarters Address	198 Champion Court, San Jose, CA 95134
U.S. Infineon Headquarter Contact Info	(408) 943-2600
Infineon website address	http://www.infineon.com

11 Acronyms

Table 54 Acronyms used in this document

Acronym	Description
BLE	Bluetooth® Low-energy
Bluetooth® SIG	Bluetooth® Special Interest Group
CE	European Conformity
CSA	Canadian Standards Association
EMI	electromagnetic interference
ESD	electrostatic discharge
FCC	Federal Communications Commission
GPIO	general-purpose input/output
IC	Industry Canada
IDE	integrated design environment
KC	Korea Certification
MIC	Ministry of Internal Affairs and Communications (Japan)
PCB	Printed circuit board
RX	receive
QDID	qualification design ID
SMT	surface-mount technology; a method for producing electronic circuitry in which the components are placed directly onto the surface of PCBs
TCPWM	timer, counter, pulse-width modulation
TUV	Germany: Technischer Überwachungs-Verein (Technical Inspection Association)
TX	transmit

12 Document conventions

12.1 Units of measure

Table 55 Unit of measures

Symbol	Unit of measure
°C	degree Celsius
kV	kilovolt
mA	milliamperes
mm	millimeters
mV	millivolt
µA	microamperes
µm	micrometers
MHz	megahertz
GHz	gigahertz
V	volt
dB	decibel
ms	millisecond
µs	microsecond
ns	nanosecond
pF	picofarad
kΩ	kiloohm

Revision history

Document revision	Date	Description of changes
**	2015-02-18	Preliminary data sheet for CYBLE-022001-00 module.
*A	2015-03-09	Updated Overview: Updated Module description: Updated Module dimensions and drawing: Updated Figure (Updated Module Pad Assignment). Updated Recommended host PCB layout: Updated Table 3: Updated table caption to read as “Module Solder Pad Connection Dimensions”. Updated Table 4: Changed Pad 10 from NC to GND. Updated Power supply connections and recommended external components: Updated External component recommendation: Updated Figure (Changed Pad 10 from NC to GND). Updated Figure 8 (Changed Pad 10 from NC to GND). Updated Figure 9 (Changed Pad 10 from NC to GND).
*B	2015-04-01	Updated Document Title to read as “CYBLE-022001-00, EZ-BLE™ Creator Module”. Replaced terms “pre-certified” with “certified” and “pre-qualified” with “qualified” respectively in all instances across the document. Updated General description: Updated Module description: Updated description. Added hyperlinks in required places. Updated Power consumption: Updated description. Updated Functional capabilities: Updated description. Updated Electrical specification: Updated Table 10: Updated details in “Details/Conditions” column of T_{STOP} parameter to “XRES wakeup”. Updated Acronyms: Added “QDID”.
*C	2015-06-23	Changed status from Preliminary to Final. Updated General description: Updated Module description: Updated description. Updated Functional capabilities: Change number of capacitive sensors supported from 13 to 15. Updated Power supply connections and recommended external components: Updated Power connections: Updated description. Updated Figure 9 (To final design schematic). Updated Electrical specification: Updated Table 9: Changed typical value of I_{DD15} from 1.3 μA to 1.5 μA. Updated Ordering information: No change in part numbers. Added Part numbering convention. Added Packaging. Updated Acronyms: Added “SMT”.

Revision history

Document revision	Date	Description of changes
*D	2015-12-14	Updated General description: Updated description. Added hyperlinks in required places. Added More information. Updated Overview: Updated Module description: Updated Module dimensions and drawing: Updated Figure (to improve clarity and viewing). Updated Pad connection interface: Updated description. Updated Figure (to improve clarity and viewing). Updated Figure 4 (to improve clarity and viewing). Updated Recommended host PCB layout: Updated Figure (to improve clarity and viewing). Added Figure (to show solder pad location from module origin). Updated Table 3(to provide the location to the center of each solder pad from the origin (in mm and mils)). Added Figure (to provide the location to the center of each solder pad from the origin (in mm and mils)). Updated Electrical specification: Updated XRES: Added Temperature sensor. Added SAR ADC. Added CSD. Updated Digital peripherals: Added Timer. Added Counter. Added Pulse Width Modulation (PWM). Added LCD direct drive. Updated System resources: Added Bluetooth® LE subsystem. Updated ISED: Updated description (Added French translation for IC Radiation Exposure Statement for Canada in accordance with IC requirements). Updated Packaging: Added Table 50. Added Table 51. Completing Sunset Review.

Revision history

Document revision	Date	Description of changes
*E	2016-02-22	Updated General description: Updated Module description: Re-ordered descriptions. No change to content. Updated Overview: Updated Module description: Updated Module dimensions and drawing: Updated Figure 1 (changed orientation to match PSoC™ Creator). Updated Pad connection interface: Updated Figure 2 (changed orientation to match PSoC™ Creator). Updated Figure 3 (changed orientation to match PSoC™ Creator). Updated Recommended host PCB layout: Updated Figure 4 (changed orientation to match PSoC™ Creator). Updated Figure 5 (changed orientation to match PSoC™ Creator). Updated Figure 6 (changed orientation to match PSoC™ Creator). Updated Table 4 (Added additional information with respect to the functional capabilities for each solder pad). Updated Power supply connections and recommended external components: Updated External component recommendation: Updated Figure (changed orientation to match PSoC™ Creator). Updated Figure 8 (changed orientation to match PSoC™ Creator). Updated Figure 9 (changed orientation to match PSoC™ Creator). Updated Packaging: Updated Figure 13 (changed orientation to match PSoC™ Creator).
*F	2016-09-02	Updated More information: Updated description. Updated hyperlinks. Updated Electrical specification: Updated System resources: Updated Internal low-speed oscillator: Updated Table 6: Updated details in “Value” column corresponding to ECO_{TRIM} parameter. Updated Environmental specifications: Added Safety certification. Updated Ordering information: No change in part numbers. Added Table 53 (To specify minimum and maximum reel quantities that ship for orders of the CYBLE-022001-00 module). Updated to new template.
*G	2016-11-23	Updated Two easy-to-use design environments to get you started quickly: Added AIROC™ Bluetooth® & Bluetooth® LE module firmware platform. Updated Recommended host PCB layout: Updated Figure 4. Updated Figure 5. Updated Figure 6. Updated Power supply connections and recommended external components: Updated External component recommendation: Updated Figure. Updated Figure 8. Updated Digital and analog capabilities and connections: Updated Table 4: Updated details under “TCPWM” column (to add TCPWM capability on Port 2 pins). Added Note 3 and referred the same note in “TCPWM” column.

Revision history

Document revision	Date	Description of changes
*H	2016-12-14	Updated Electrical specification : Updated SAR ADC : Updated Table 18 : Added Note 9 and referred the same note in “Details/Conditions” column corresponding to A_CHNIS_S and A-CHNKS_D parameters. Completing Sunset Review.
*I	2017-04-18	Updated Cypress Logo and Copyright.
*J	2017-12-22	Updated Packaging : Updated Figure 10 (Updated reel dimensions). Updated Figure 12 (Updated reel dimensions). Completing Sunset Review.
*K	2018-03-08	Updated Document Title to read as “CYBLE-022001-00, EZ-BLE™ Creator Module”. Replaced “PProC™ Module” and “PProC Module” with “Creator Module” in all instances across the document. Replaced “PProC™ BLE” and “PProC BLE” with “PSoC™ 4 BLE” and “PSoC 4 BLE” in all instances across the document. Updated General description : Updated Module description : Updated description. Updated More information : Updated description. Updated hyperlinks. Updated Environmental specifications : Updated Environmental compliance : Updated description. Updated Regulatory information : Updated ISED : Updated description. Updated Ordering information : No change in part numbers. Updated Part numbering convention .
*L	2019-07-03	Updated Regulatory information : Updated European R&TTE declaration of conformity : Replaced 1999/5/EC with 2014/53/EU. Updated to new template.
*M	2020-09-02	Updated General description : Updated hyperlinks. Updated description. Updated Module description : Updated description. Updated hyperlinks. Updated More information : Updated hyperlinks. Updated Two easy-to-use design environments to get you started quickly : Updated PSoC™ Creator Integrated Design Environment (IDE) : Updated PSoC™ Creator Component Datasheet - Bluetooth Low Energy (BLE) : Updated hyperlinks. Updated description. Updated Regulatory information : Added Packaging . Updated to new template.

Revision history

Document revision	Date	Description of changes
*N	2020-13-23	Replaced “Bluetooth® Low Energy (BLE)” with “Bluetooth® Low Energy” in all instances across the document. Replaced “BLE” with “Bluetooth® LE” in all instances across the document.
*O	2021-03-29	No technical updates. Completing Sunset Review.
*P	2023-03-30	Removed ANATEL section. Migrated to Infineon template.

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Do you have a question about this document?

Email:
erratum@infineon.com

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